

Microwave Receiver Systems

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Tinus Stander

Carl and Emily Fuchs Institute for Microelectronics

Dept. EEC Engineering, University of Pretoria

tinus.stander@up.ac.za

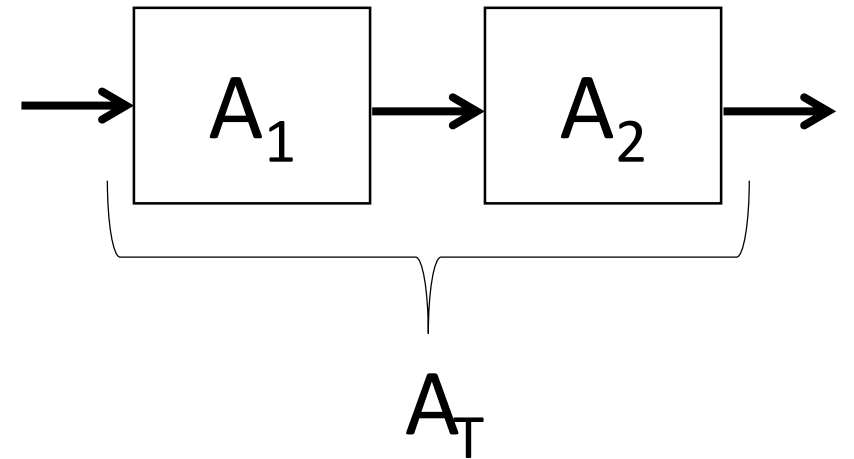
Agenda

- Key RF principles
- Noise & Distortion
- Receiver architectures
- Important RF circuits
- RF measurement equipment

RF Basics

The Decibel (dB)

- Used wherever we have a ratio
 - Usually loss or gain
- $A_T = A_1 \times A_2$
- Power: $A_X \text{ (dB)} = 10\log(A_X)$
- Voltage / Current / S-parameters:
 $A_X \text{ (dB)} = 20\log(A_X)$
- $A_T \text{ (dB)} = A_1 \text{ (dB)} + A_2 \text{ (dB)}$
- $A > 0 \text{ dB}$: gain
- $A < 0 \text{ dB}$: loss



The S-parameter (Scattering Matrix)

- Incident and reflected voltage wave relationships
 - Frequency variant
 - Complex
- All ports terminated Z_0
- Important ones for $N = 2$:
 - S_{21} : Forward transmission
 - S_{11} : Input reflection
 - S_{22} : Output reflection
 - S_{12} : Reverse transmission
- Reciprocal: $S_{21} = S_{12}$

$$\begin{bmatrix} V_1^- \\ V_2^- \\ \vdots \\ V_N^- \end{bmatrix} = \begin{bmatrix} S_{11} & S_{12} & \cdots & S_{1N} \\ S_{21} & & & \vdots \\ S_{N1} & \cdots & & S_{NN} \\ \vdots & & & \end{bmatrix} \begin{bmatrix} V_1^+ \\ V_2^+ \\ \vdots \\ V_N^+ \end{bmatrix}$$

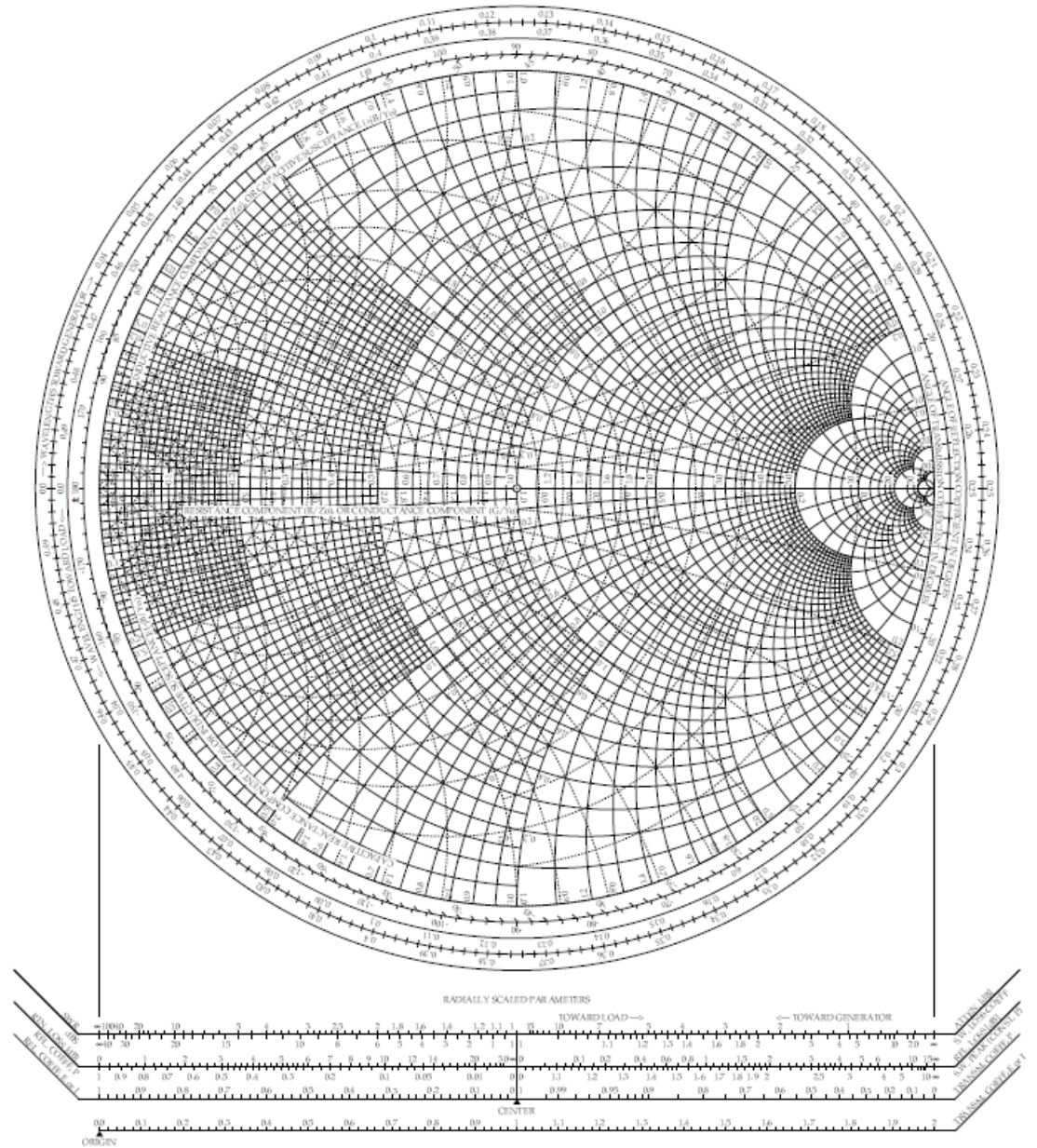
$$S_{ij} = \left. \frac{V_i^-}{V_j^+} \right|_{V_k^+ = 0 \text{ for } k \neq j}$$

$$[S] = \begin{bmatrix} 0.15 \angle 0^\circ & 0.85 \angle -45^\circ \\ 0.85 \angle 45^\circ & 0.2 \angle 0^\circ \end{bmatrix}$$

Smith chart

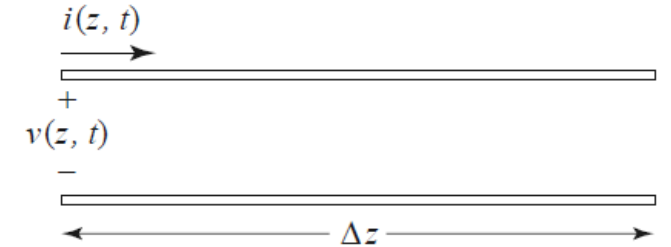
- Superimpose Z on Γ
 - For given Z_0 !
- Basic “Movements”
 - Shunt L,C
 - Series L,C
 - Cascaded TX line

$$Z_{in} = Z_0 \frac{1 + \Gamma e^{-2j\beta l}}{1 - \Gamma e^{-2j\beta l}},$$



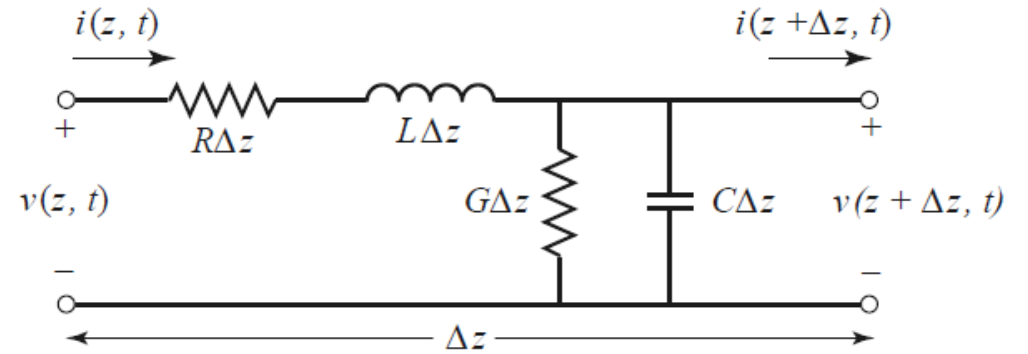
Wires and Interconnects

- DC approximation: $i(z=0) = i(z = z_x)$, $v(z=0)=v(z=z_x)$
- Non-negligible other effects:
 - Inductance
 - Resistance
 - Stray capacitance (get to that with TX lines)
- Lumped Element approximation: $z_x \ll \lambda/10 \rightarrow \lambda/20$



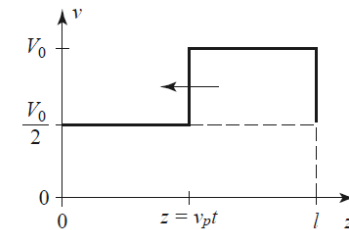
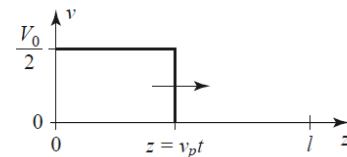
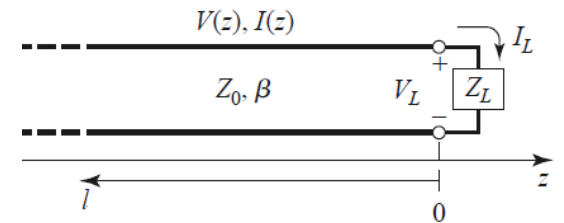
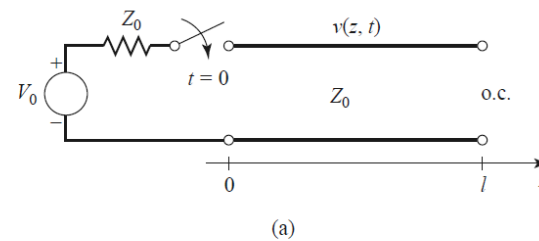
Transmission Lines

- Wave propagating along medium
 - $v(z,t)$, $i(z,t)$
 - Finite phase shift
- Medium characteristics
 - Z , β , α
 - Reflection
- TEM modes
 - Nondispersive, 2+ conductors
- TE, TM modes
 - Dispersive, 1+ conductor



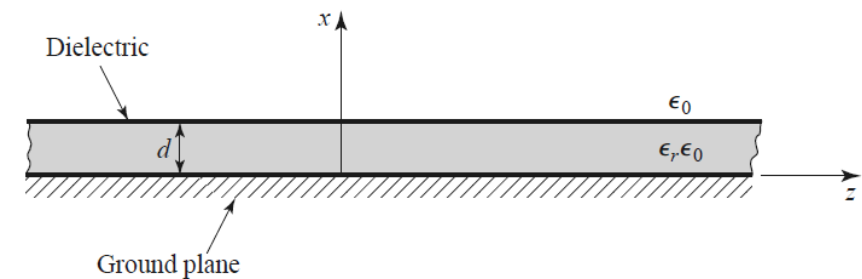
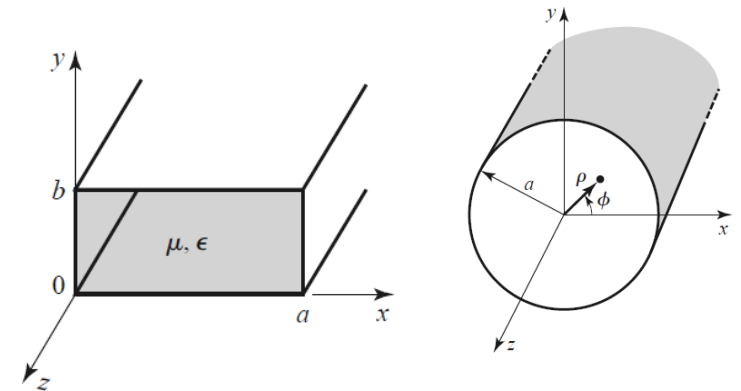
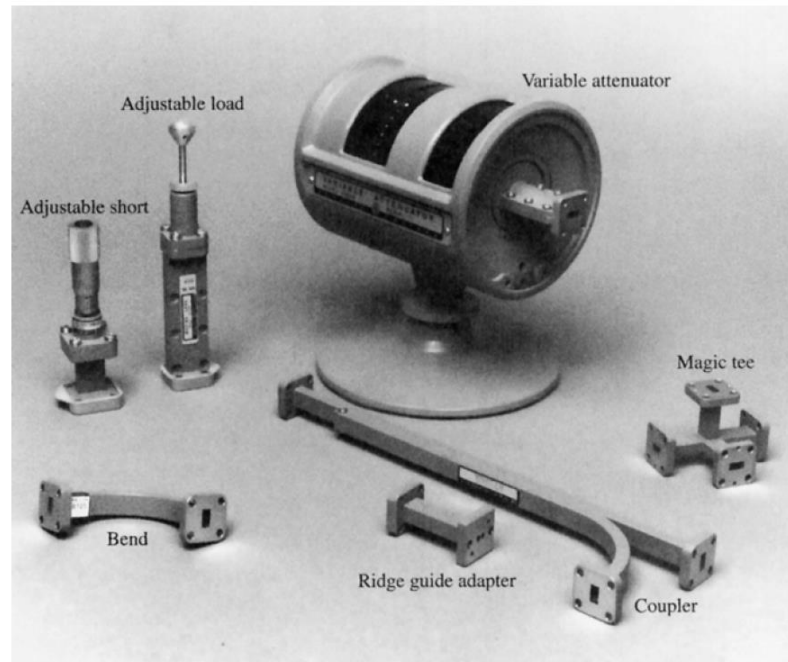
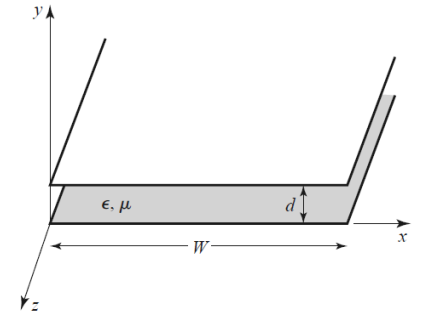
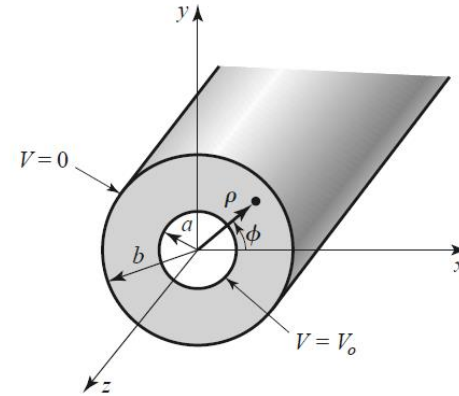
$$v_p = \frac{\omega}{\beta} = \lambda f, \quad Z_0 = \sqrt{\frac{L}{C}}, \quad \lambda = \frac{2\pi}{\beta} = \frac{2\pi}{\omega\sqrt{LC}}$$

$$\alpha \simeq \frac{1}{2} \left(R\sqrt{\frac{C}{L}} + G\sqrt{\frac{L}{C}} \right) = \frac{1}{2} \left(\frac{R}{Z_0} + GZ_0 \right)$$



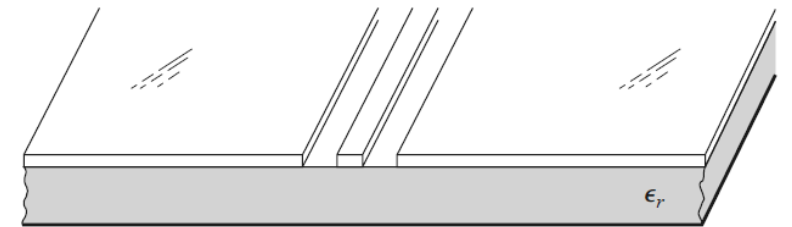
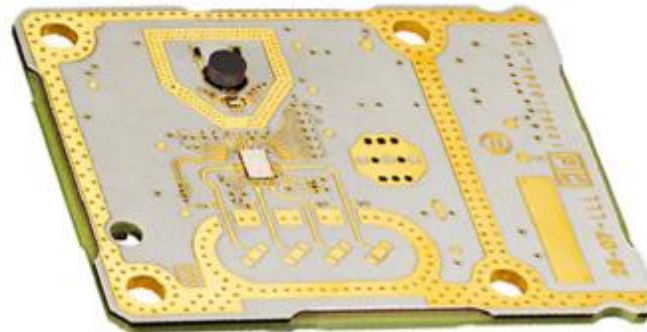
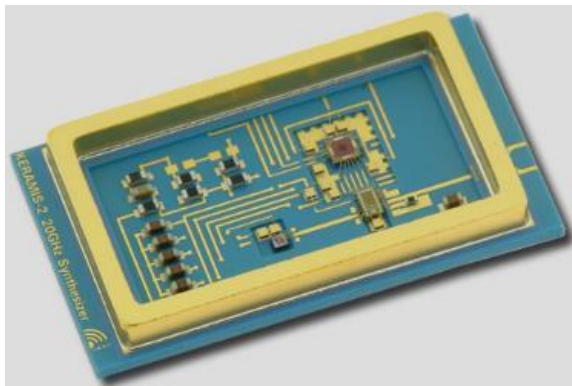
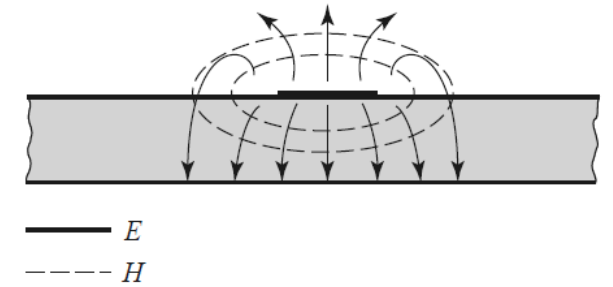
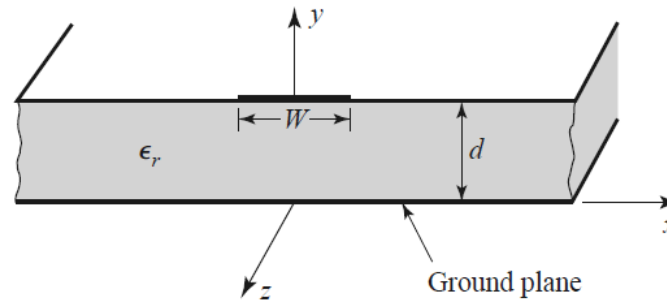
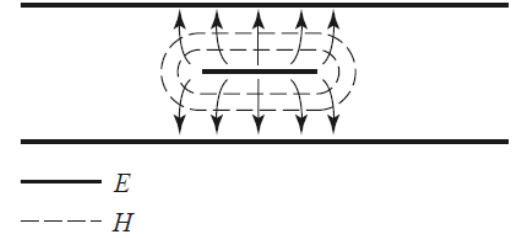
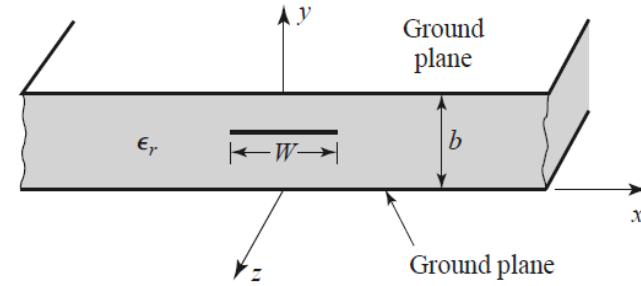
Transmission media (1)

- Waveguide
 - Coax
 - Modes!
 - Parallel Plate
 - Parasitic!
 - Surface Waves
 - Parasitic!
 - Rectangular, Circular



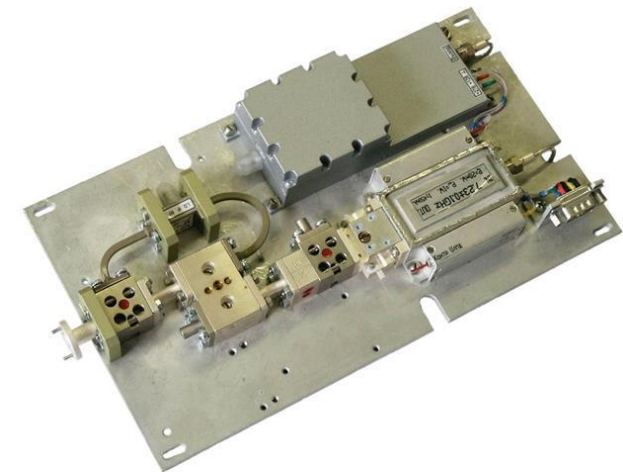
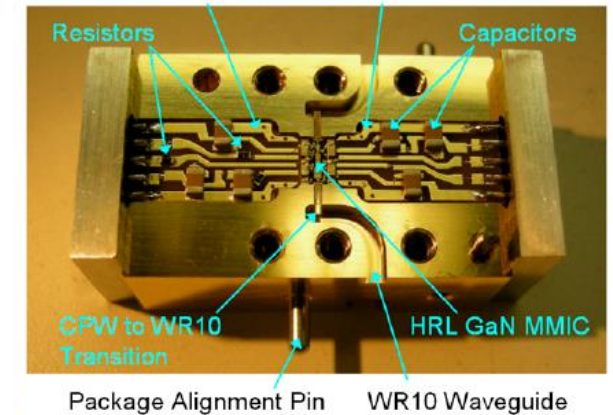
Transmission media (2)

- Planar
 - Stripline
 - Microstrip
 - CPW, GCPW
 - And others...
- Integrate with SMD components



Non-planar system integration

- Waveguide
 - Split block / finline
 - WR standards
- Microwave coax connectors
 - Different standards for different frequencies
 - SMA most common
- Mixed modules
 - WG RF, coax IF
- Cables
 - Limited by overmoding, connectors



Impedance matching

- Maximum power delivery between matched source and load
- Sometimes a specific source impedance is sought
 - We'll get to that later
- In cases of mismatch: impedance matching network

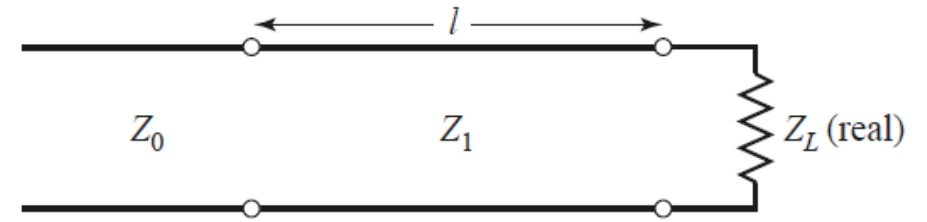
$$Z_{\text{in}} = Z_0 \frac{1 + \Gamma_{\ell} e^{-2j\beta l}}{1 - \Gamma_{\ell} e^{-2j\beta l}} = Z_0 \frac{Z_{\ell} + jZ_0 \tan \beta l}{Z_0 + jZ_{\ell} \tan \beta l},$$

$$\Gamma_{\ell} = \frac{Z_{\ell} - Z_0}{Z_{\ell} + Z_0}.$$

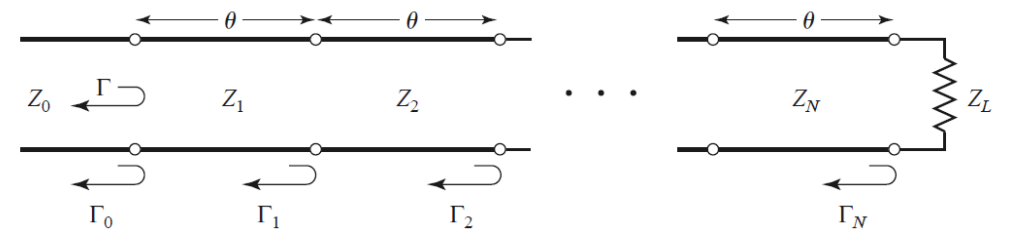
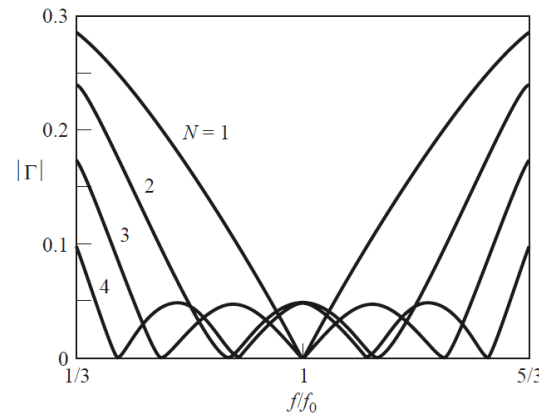
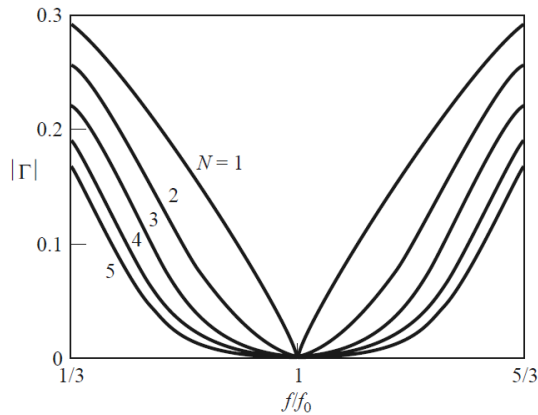
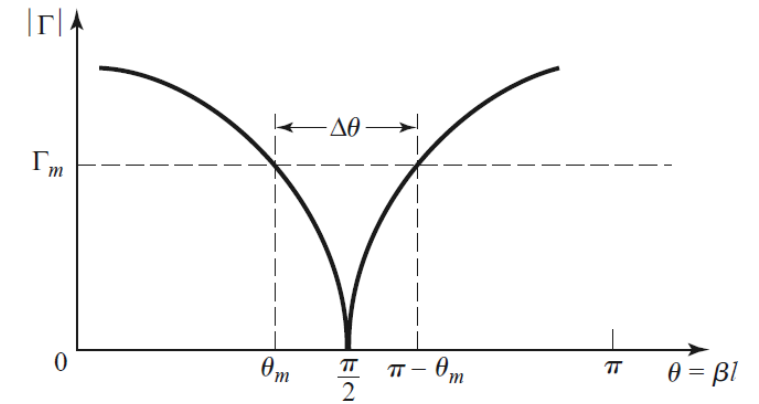


Cascaded line transformer

- Typ. used for real-impedance matching
- Simplest: quarter-wave
 - Single frequency
- Cascade multiple sections: broadband
 - Binomial, Chebyshev

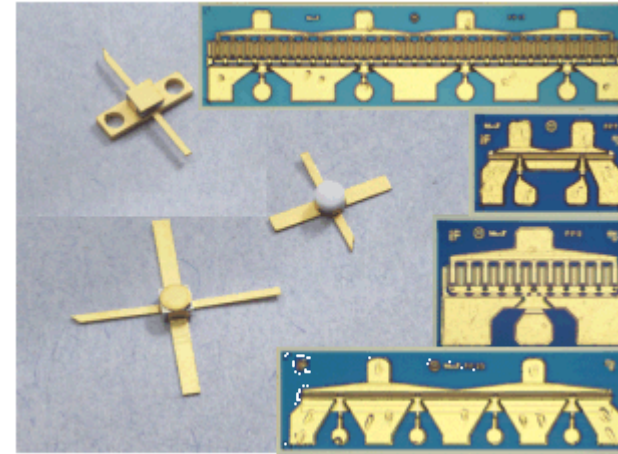


$$Z_1 = \sqrt{Z_0 Z_L}.$$

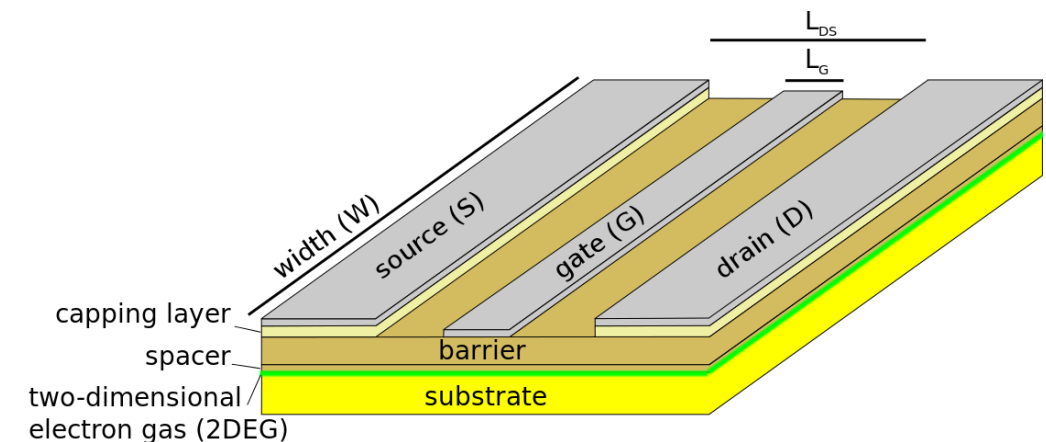
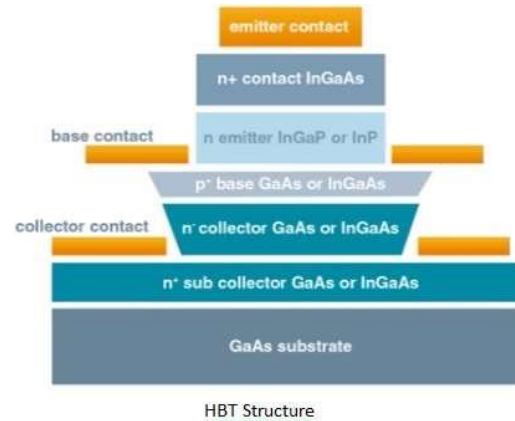


Transistors

- Different semiconductors
 - Si: Cheap, moderate performance
 - SiGe: More expensive, faster III-V
 - GaAs: Common in Radio Astronomy
 - InP: The best, most expensive choice
- Types
 - Bipolar: BJT / HBT
 - MOSFET, MESFET
 - HEMT

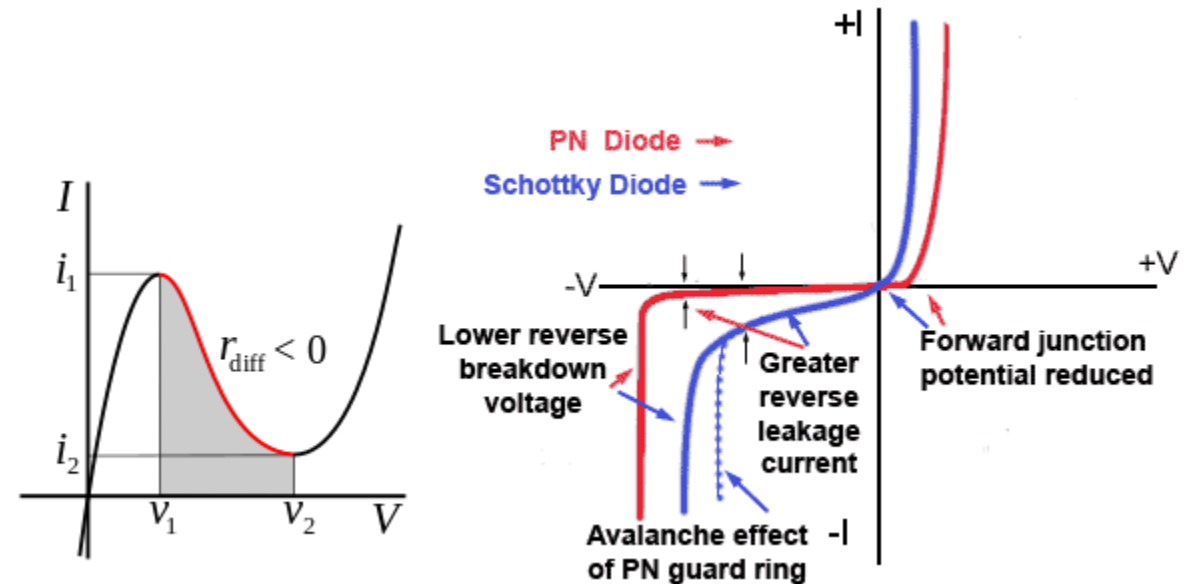
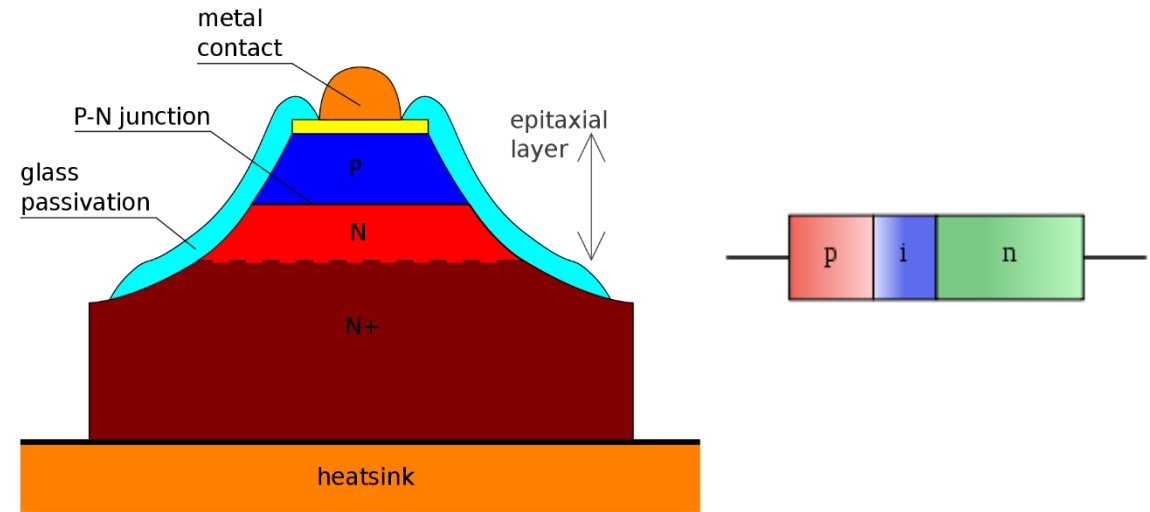


	IIIA	IVA	VA	VIA	VIIA	
III-V	B Boron	C Carbon	N Nitrogen	O Oxygen	F Fluorine	
	Al Aluminum	Si Silicon	P Phosphorus	S Sulphur	Cl Chlorine	
IB	IIB	Ga Gallium	Ge Germanium	As Arsenic	Se Selenium	Br Bromine
Cu Copper	Zn Zinc	In Indium	Sn Tin	Sb Antimony	Te Tellurium	I Iodine
Ag Silver	Cd Cadmium	Tl Thallium	Pb Lead	Bi Bismuth	Po Polonium	At Astatine
Au Gold	Hg Mercury					



Diodes

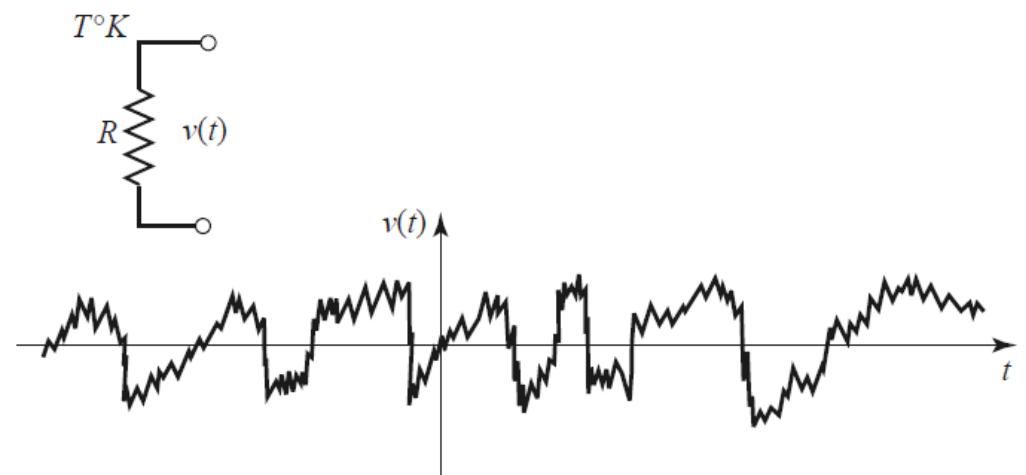
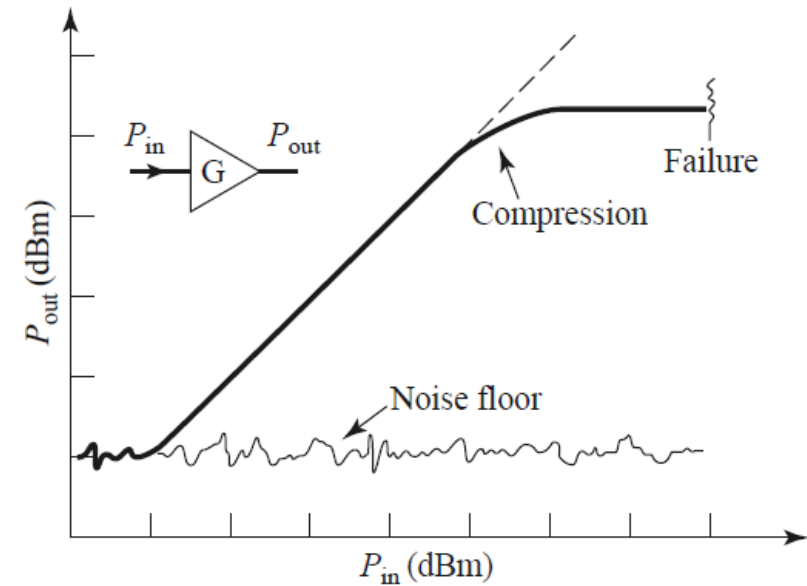
- PN: low frequency
 - Varactor: Vary C with DC (depletion layer)
- PIN
 - DC biasing -> very linear R at RF
 - I layer stores charge
 - Switches, variable attenuators
- Schottky
 - Metal-semi contact
 - Fast switching; no recovery time
 - Detectors
- Tunnel Diode
 - Negative I-V region
 - Quantum well
 - Detectors, switches



Noise

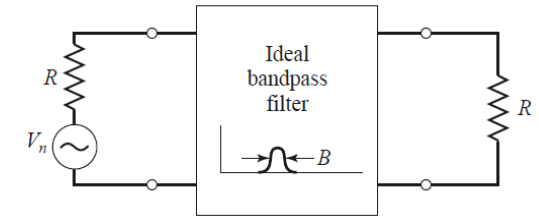
General principles (1)

- Random variation
 - Internal: charge carriers
 - Thermal noise (Johnson / Nyquist)
 - Shot noise
 - Flicker (1/f) noise
 - External: physical phenomenon
 - Thermal emissions, cosmic background
 - Sources = interferers, not noise
 - Flat spectrum = “white noise”
 - Zero average, nonzero RMS
- Limits dynamic range
 - Other end: compression / distortion

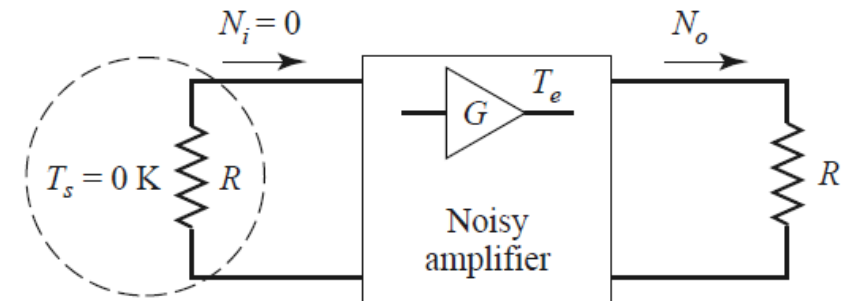


General principles (2)

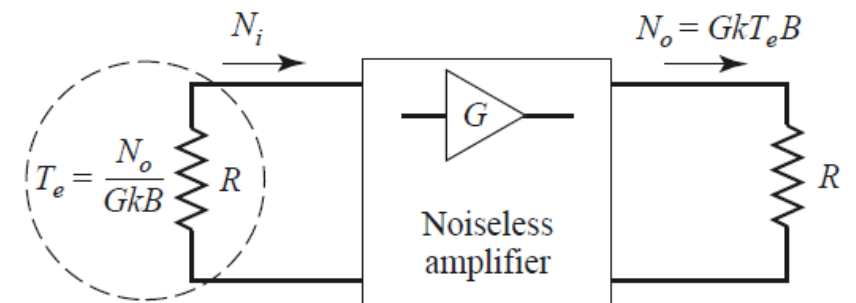
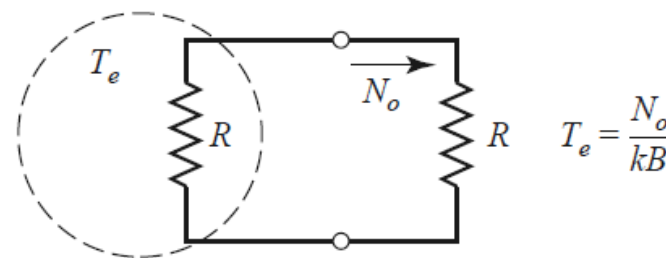
- Link between noise and temperature
- Planck blackbody
 - Rayleigh-Jeans approx. okay, except
 - $f > 1 \text{ THz}$, $K \ll 300\text{K}$
- Equivalent noise temperature
- Used for noise-generating components
- Used for antennas



$$V_n = \sqrt{4kTBR}.$$



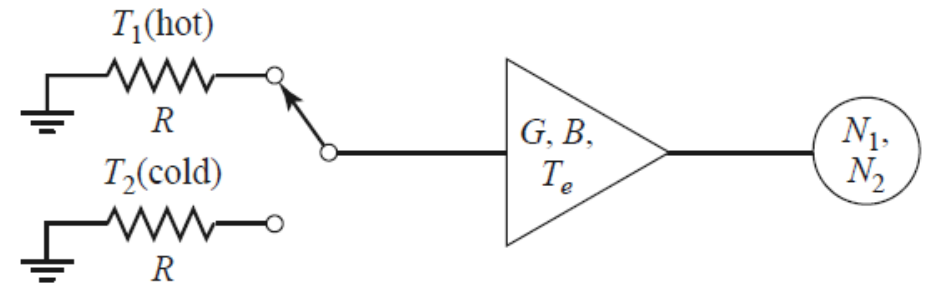
(a)



(b)

Noise Measurement

- Y-factor method
- Switch between “hot” and “cold” loads
- Need $Y \gg 1$
 - $T_1 \gg T_2$
 - $T_1, T_2 \gg T_e$
- Re-write i.t.o. ENR: T_1/T_2
 - ENR tables provided in noise sources

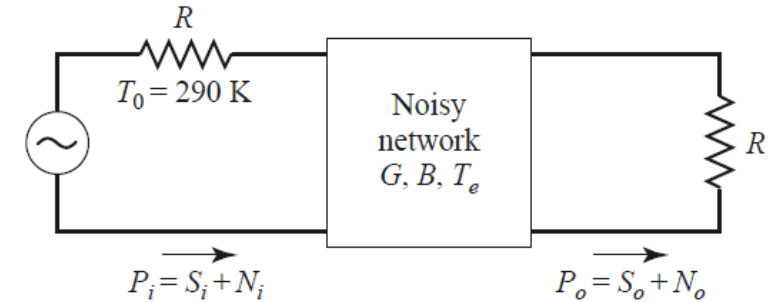


$$N_1 = GkT_1B + GkT_eB, \quad Y = \frac{N_1}{N_2} = \frac{T_1 + T_e}{T_2 + T_e} > 1,$$
$$N_2 = GkT_2B + GkT_eB,$$

$$T_e = \frac{T_1 - YT_2}{Y - 1},$$

Noise Figure

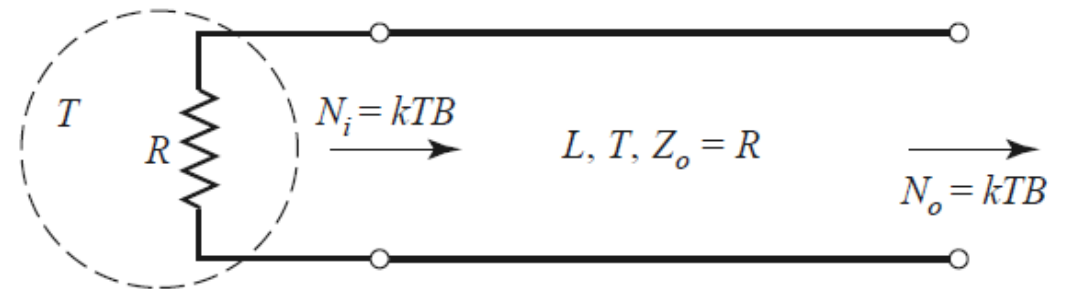
- Measure of $\text{SNR}_i/\text{SNR}_o, > 1$
- Nomenclature:
 - F = Noise Factor, linear
 - NF = Noise Figure, dB
- Defined for:
 - Matched load input
 - Reference T_0
 - Else: stick to T_e
 - Or: T_A , for antenna front-end.
- Passive, lossy components:
 - $\text{IL} = F$
 - Can apply to mismatch too: gain lower



$$F = \frac{S_i/N_i}{S_o/N_o} \geq 1,$$

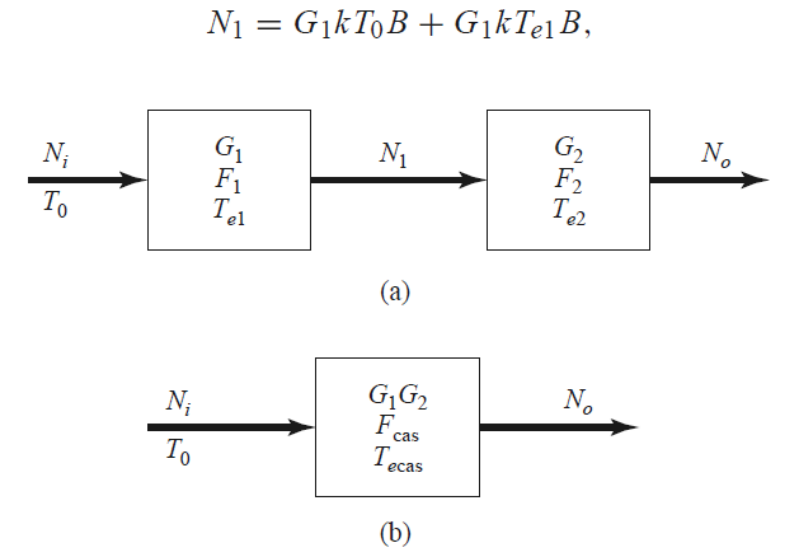
$$F = \frac{S_i}{kT_0B} \frac{kGB(T_0 + T_e)}{GS_i} = 1 + \frac{T_e}{T_0} \geq 1.$$

$$T_e = (F - 1)T_0.$$



NF in Cascaded Systems

- Amplifiers amplify gain AND noise!
 - $\text{SNR}_i/\text{SNR}_o$ increases down the chain
 - F increases
- Subsequent noise contribution mitigated by prior gain stages...
- First stage NF dominant in system!
 - Want T_A low as well.
- Use T, not NF, to avoid $T \neq T_0$



$$N_o = G_2 N_1 + G_2 k T_{e2} B$$

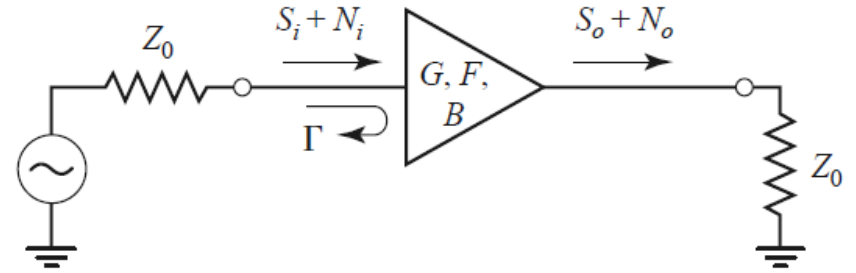
$$= G_1 G_2 k B \left(T_0 + T_{e1} + \frac{1}{G_1} T_{e2} \right).$$

$$T_{\text{cas}} = T_{e1} + \frac{T_{e2}}{G_1} + \frac{T_{e3}}{G_1 G_2} + \dots,$$

$$F_{\text{cas}} = F_1 + \frac{F_2 - 1}{G_1} + \frac{F_3 - 1}{G_1 G_2} + \dots.$$

NF of mismatched amplifiers

- F increases with mismatch

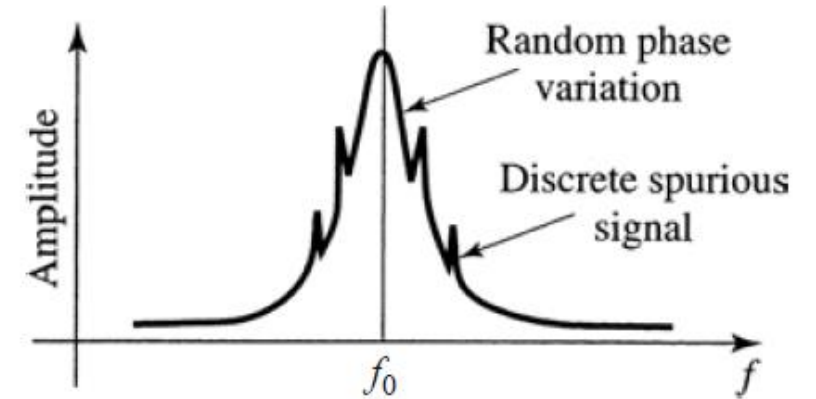


$$N_o = kT_0 GB (1 - |\Gamma|^2) + kT_0 (F - 1) GB$$

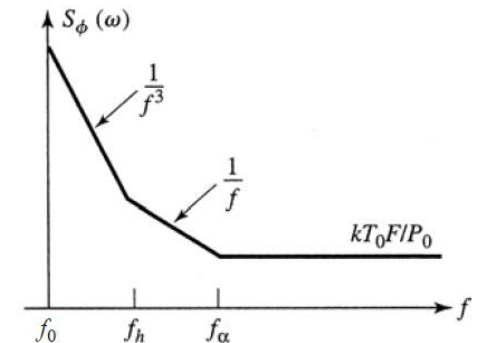
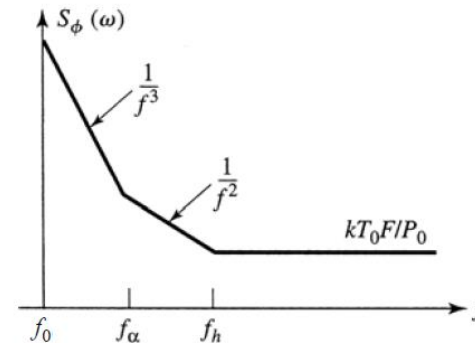
$$F_m = \frac{S_i N_o}{S_o N_i} = 1 + \frac{F - 1}{1 - |\Gamma|^2}.$$

Phase noise

- Random variation of tone f_0
 - Frequency or phase variation
 - Increase noise power
 - Error in downconversion
- Expressed in dBc/Hz @ offset f_m
- Spectrum described by Leeson's model
 - For oscillators with resonators of Q.
 - High Q reduces L
- f_α corner frequency of $1/f$
 - Transistor dependent
- Far out: amplifier NF

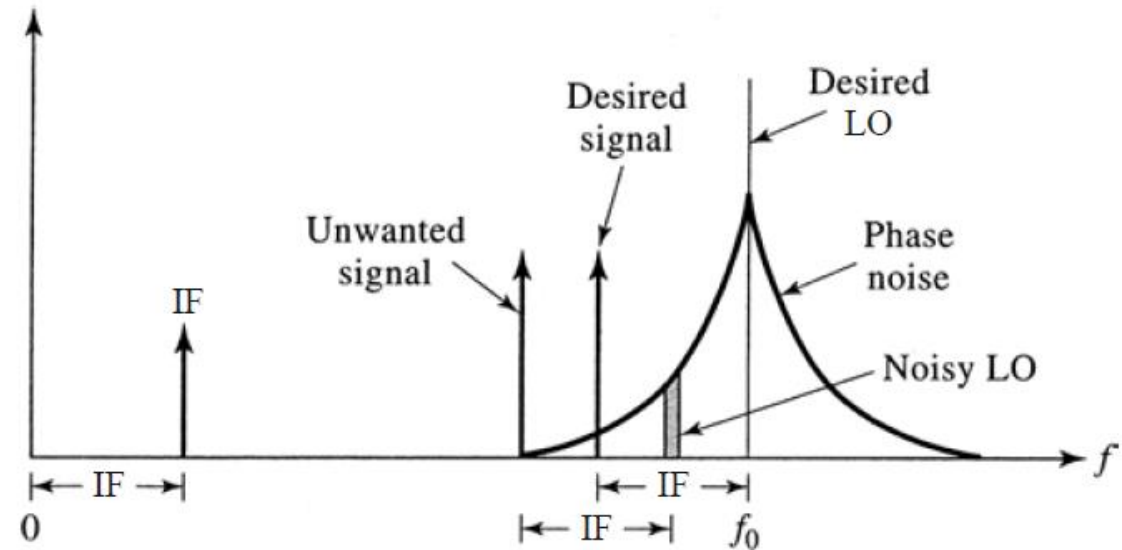


$$S_\phi(\omega) = \frac{kT_0 F}{P_0} \left(\frac{K \omega_0^2 \omega_\alpha}{4Q_0^2 \Delta\omega^3} + \frac{\omega_0^2}{4Q_0^2 \Delta\omega^2} + \frac{K \omega_\alpha}{\Delta\omega} + 1 \right)$$



Phase noise (2)

- Downconversion error
- Maximum interferer tolerable -> choice of L spec.



$$\mathcal{L}(f_m) = C \text{ (dBm)} - S \text{ (dB)} - I \text{ (dBm)} - 10 \log(B), \text{ (dBc/Hz)},$$

Distortion

Nonlinear effects & distortion

- Harmonic generation
- Saturation (gain reduction, AM-AM distortion)
- Intermodulation (two tones mix)
- AM-PM conversion (amplitude \rightarrow phase shift)
- N order of terms
 - DC, linear, quadratic, etc.

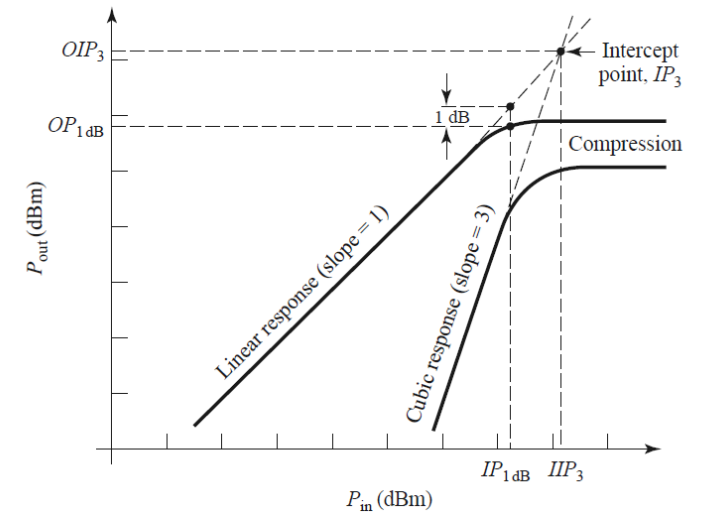
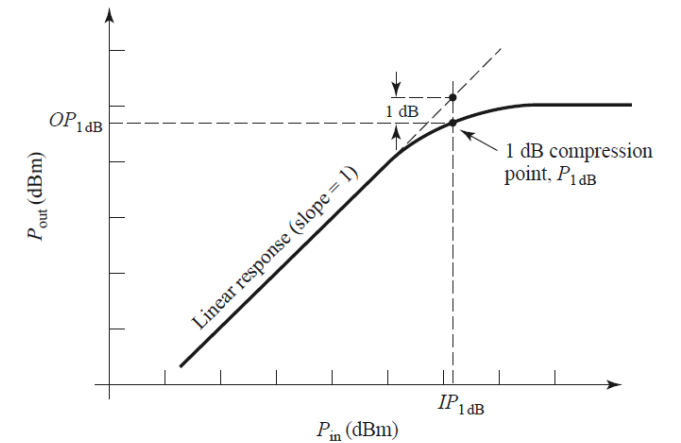


$$v_o = a_0 + a_1 v_i + a_2 v_i^2 + a_3 v_i^3 + \dots,$$

$$\begin{aligned} v_o &= a_0 + a_1 V_0 \cos \omega_0 t + a_2 V_0^2 \cos^2 \omega_0 t + a_3 V_0^3 \cos^3 \omega_0 t + \dots \\ &= \left(a_0 + \frac{1}{2} a_2 V_0^2 \right) + \left(a_1 V_0 + \frac{3}{4} a_3 V_0^3 \right) \cos \omega_0 t + \frac{1}{2} a_2 V_0^2 \cos 2\omega_0 t \\ &\quad + \frac{1}{4} a_3 V_0^3 \cos 3\omega_0 t + \dots \end{aligned}$$

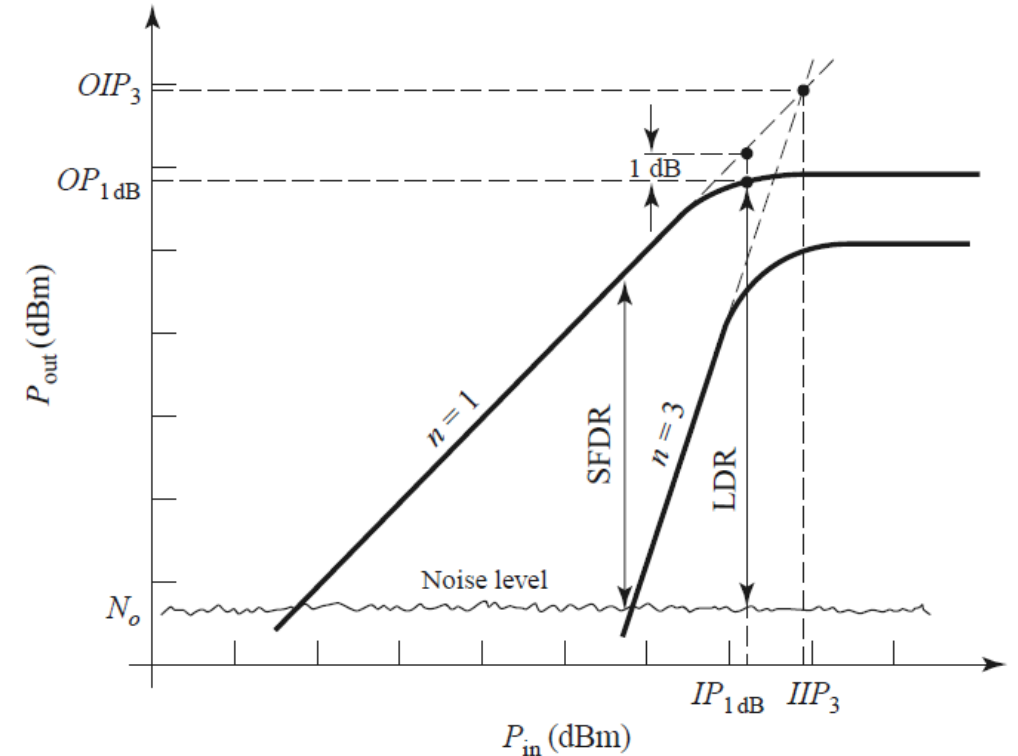
Different kinds of distortion

- Gain compression (P1db)
 - Lower than expected output
- Third order intercept (IIP3/OIP3)
 - Mixing term of two-tone input
- Passive intermodulation (PIM)
 - Parasitic diodes from oxidation on metal
 - Only a consideration at high power



Dynamic Ranges

- Power range over which performance is desirable
- Limited by which undesired effect we want to avoid!
- Linear dynamic range (LDR)
 - Range over which operation is “linear”
 - Noise floor \rightarrow P_{1dB}
- Spurious free dynamic range (SFDR)
 - Range over which spurs below noise floor
 - Typ. 3rd order ($2f_2-f_1$, $2f_1-f_2$)
 - SFDR typ. \ll LDR

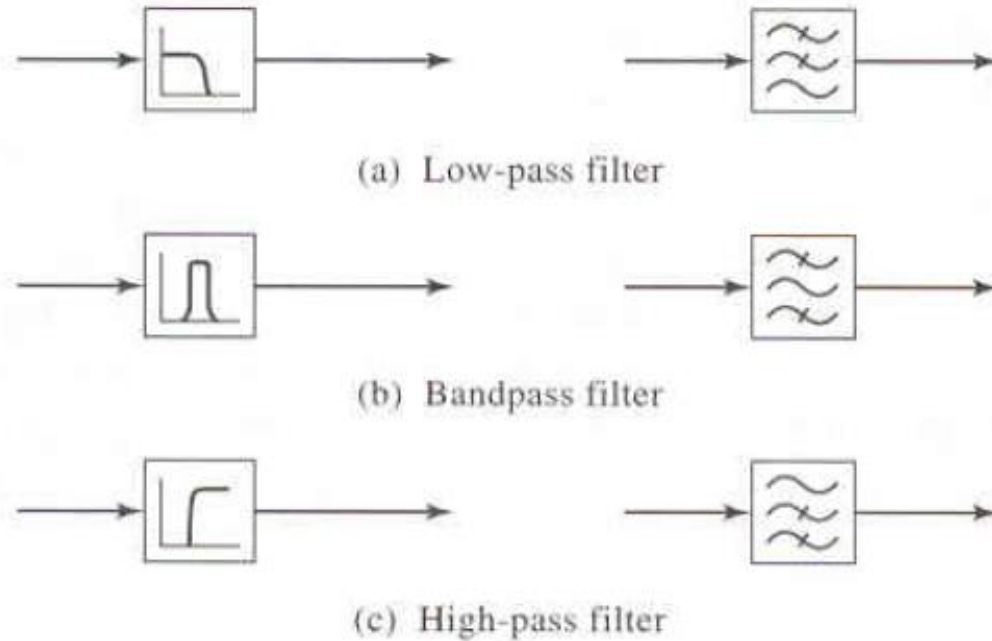


Sensitivity

- Definition specific to receiver
- Smallest detectable signal
- Sensitivity (dBm) = $-174 + NF + 10\log B + SNR$
- For antenna temperature NOT 290K
 - More generally: $S_i(\min) = kB(T_A + (F-1)T_0)SNR_{\min}$

Receiver Architectures

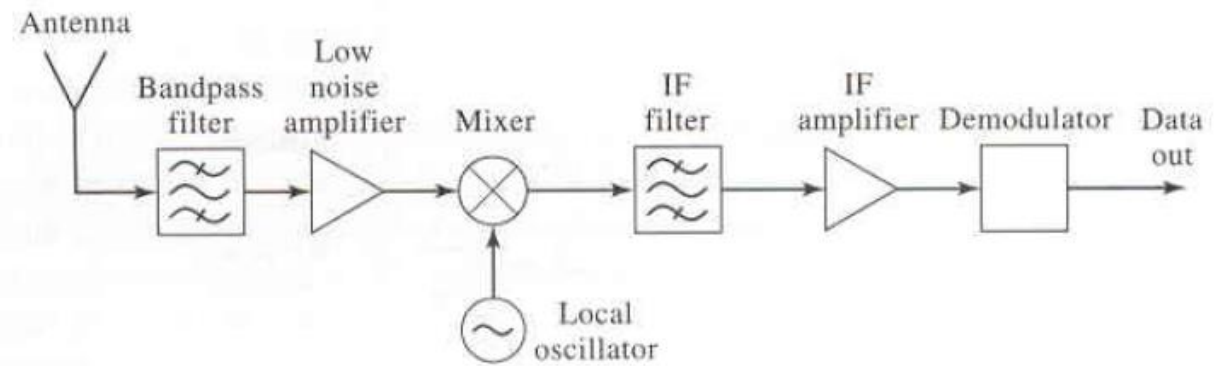
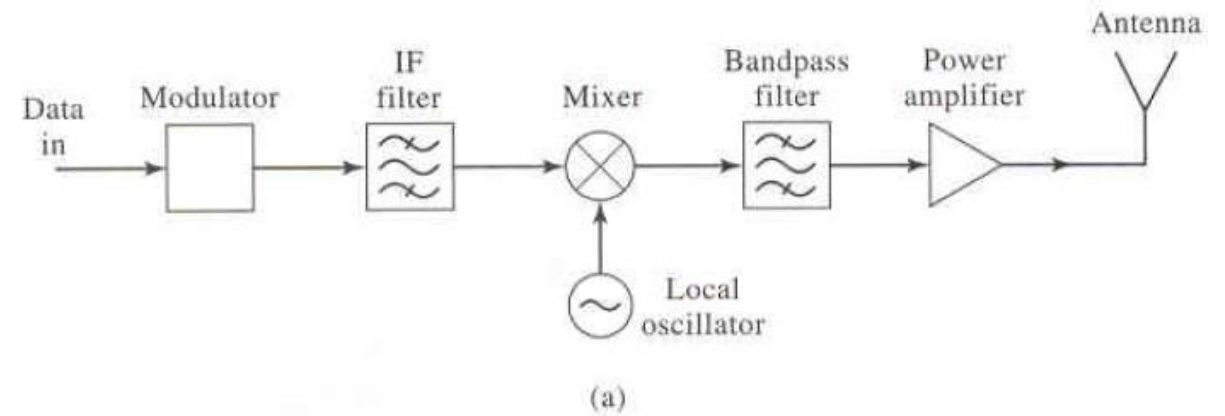
Common components



Component Symbol	Component Name
	Antenna
	Amplifier
	Mixer
	Oscillator
	90° power divider
	Frequency multiplier
	Frequency divider
	Switch

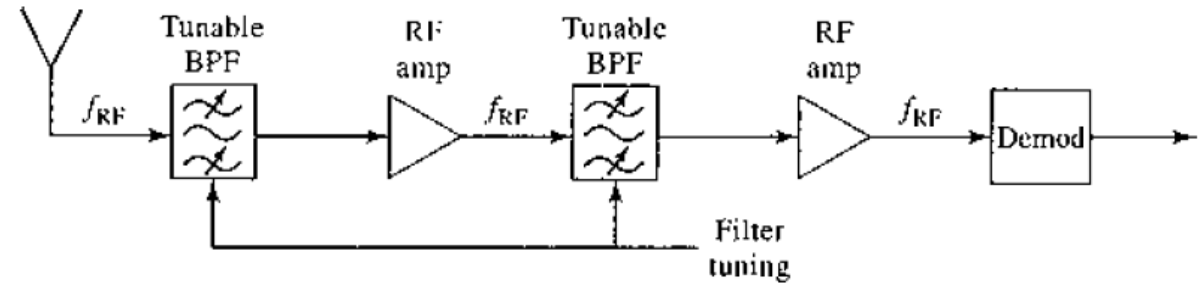
Basic TX and RX blocks

- Modulation
 - I/Q common in data
- Digitization
- Filtering
- Mixing
- Generation
- Amplification

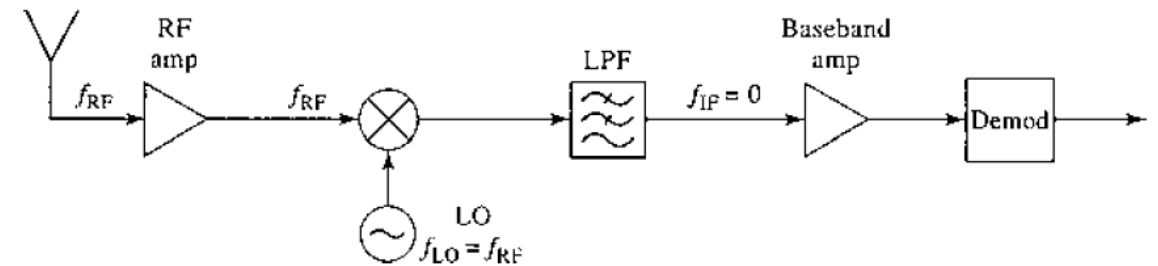


Downconversion Architectures (1)

- Tuned receivers
 - Modern: direct digitization receivers

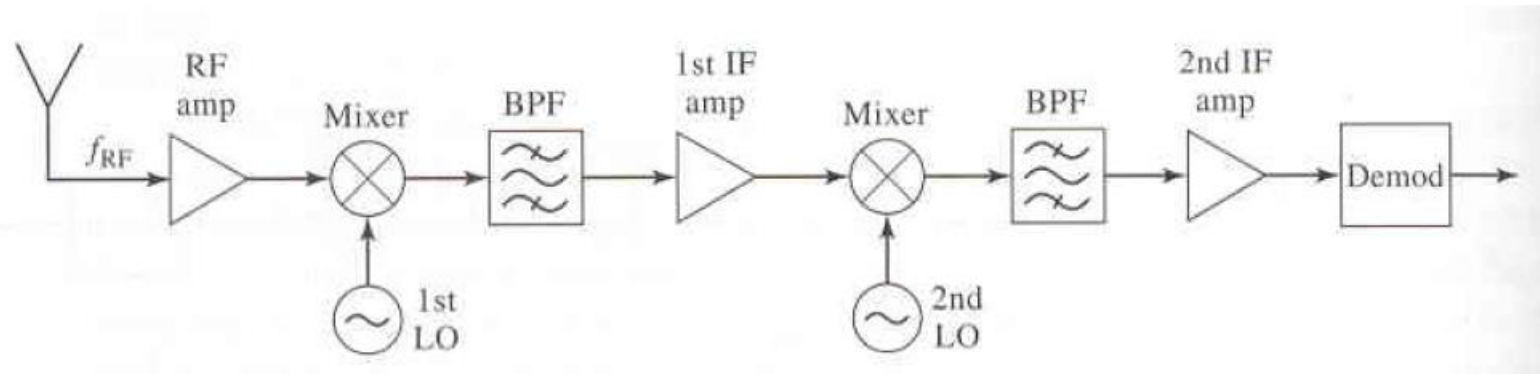
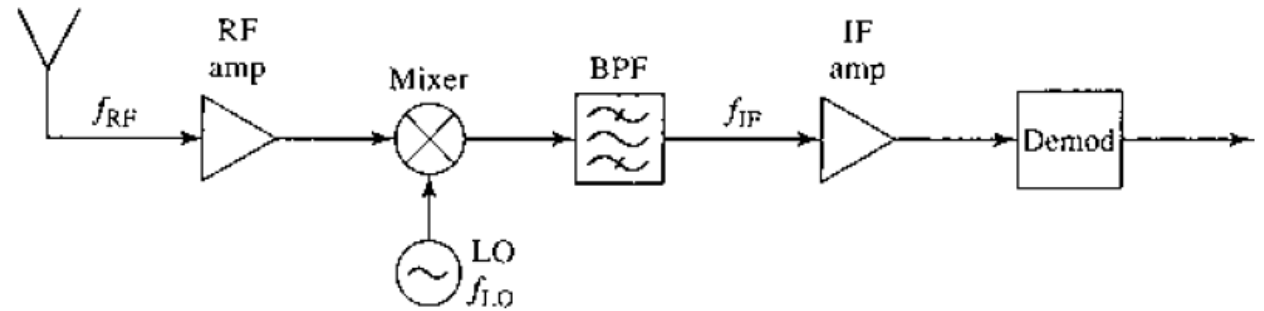


- Direct conversion receivers
 - Zero IF, homodyne
 - No image frequency
 - Stability, precision!
 - Doppler RADAR
 - Sensitive to DC offsets



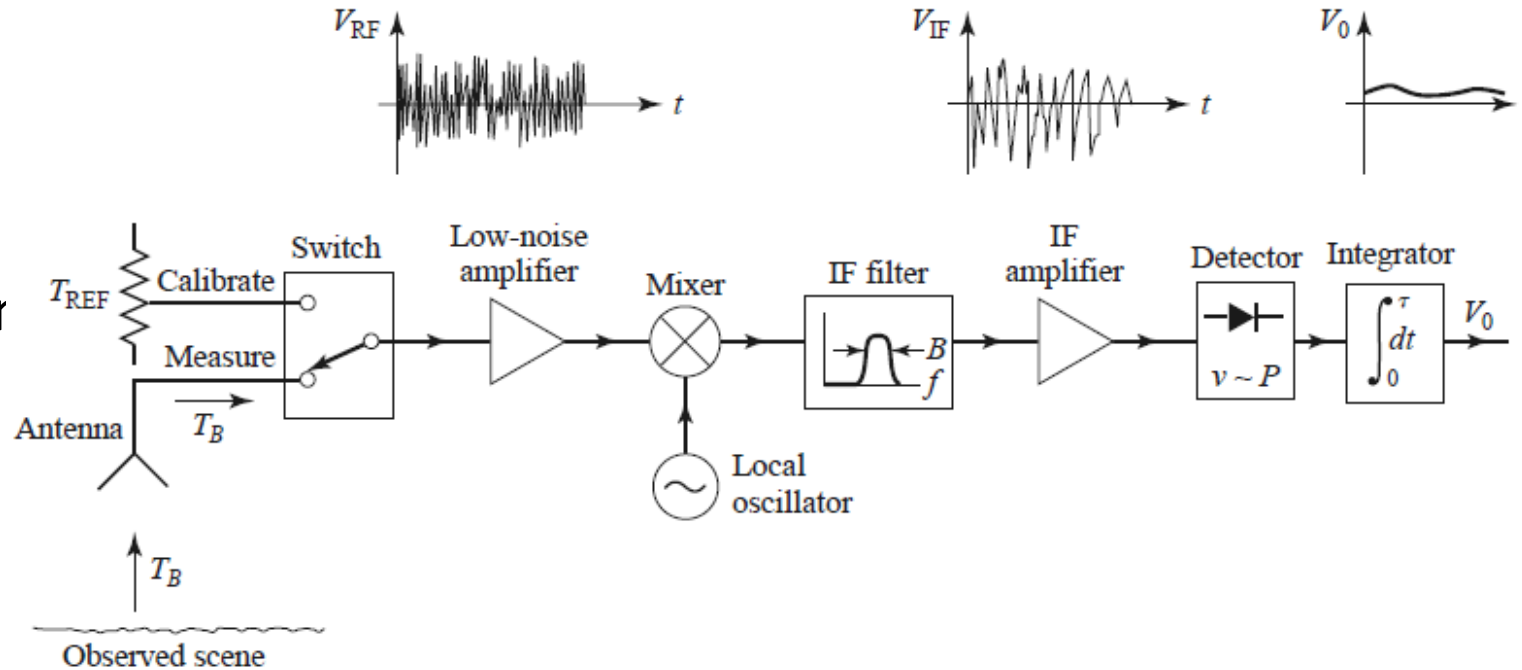
Downconversion Architectures (2)

- Superheterodyne
 - Non-zero IF (filters)
 - More stages sometimes used
 - More LOs, IFs



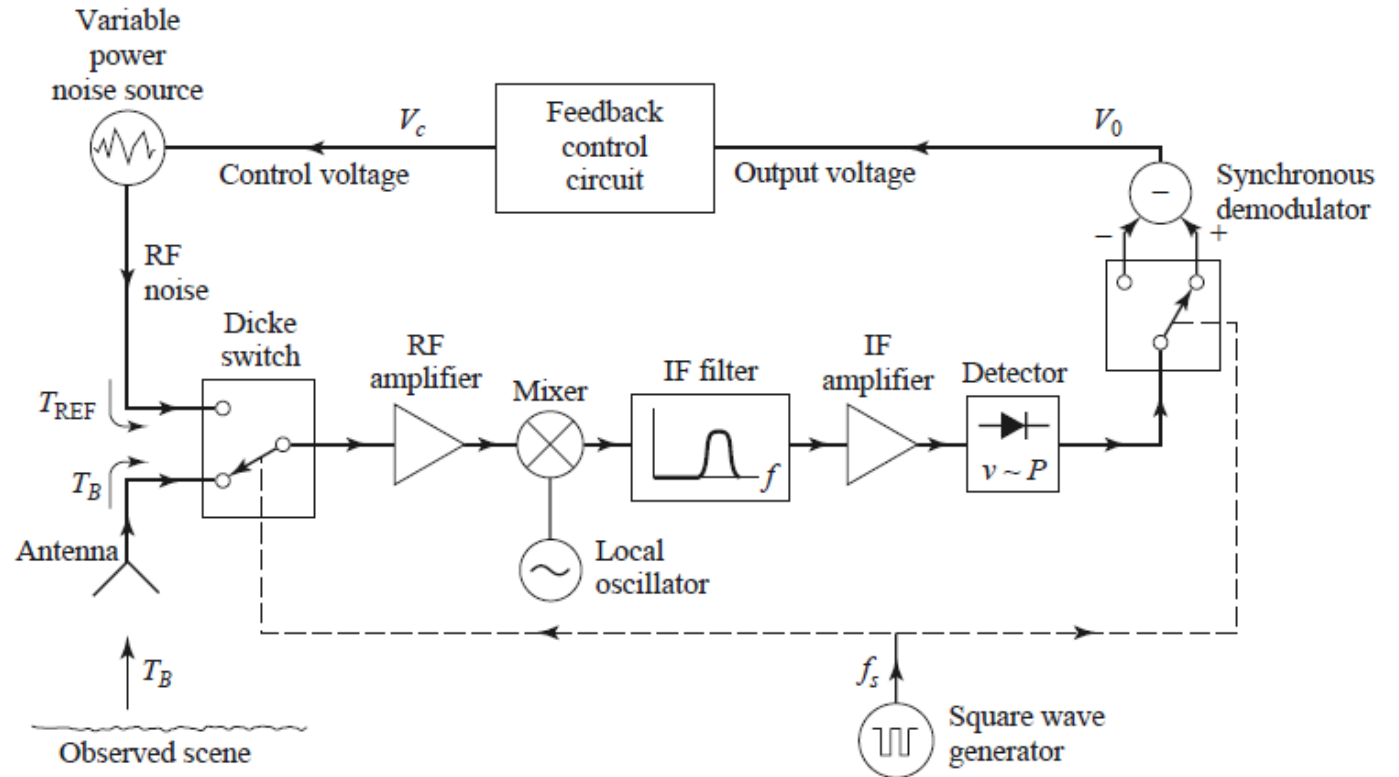
Radiometer receivers (1)

- Total power radiometer
 - Simple
 - Gain variation
 - Can't distinguish between system and observed T
 - Regular calibration!



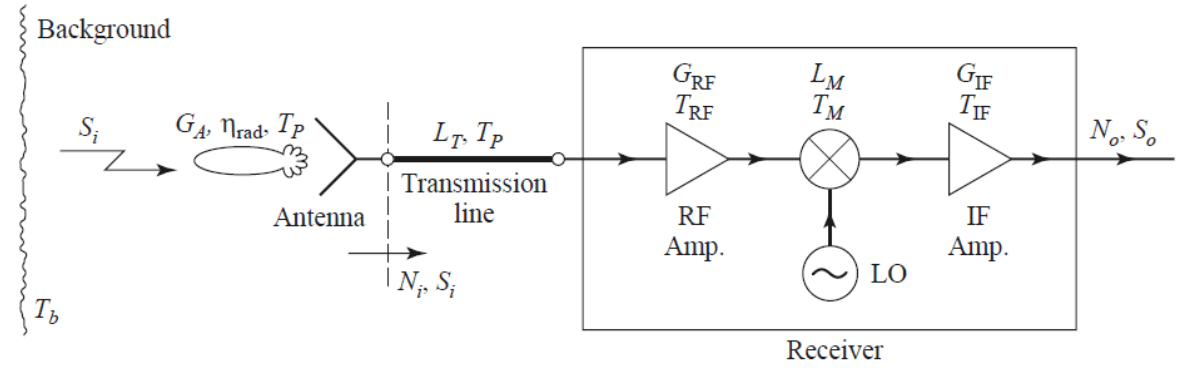
Radiometer receivers (2)

- Dicke radiometer
 - Synchronous demodulator
 - 50% scene, 50% load
 - Cancels out gain fluctuation
- Others:
 - Noise injection
 - Noise adding
 - Direct detection



Noise in receivers

- Everything generates noise
 - Loss == noise
- Noise floor increases down the chain
- Need SNR_{\min} for demod

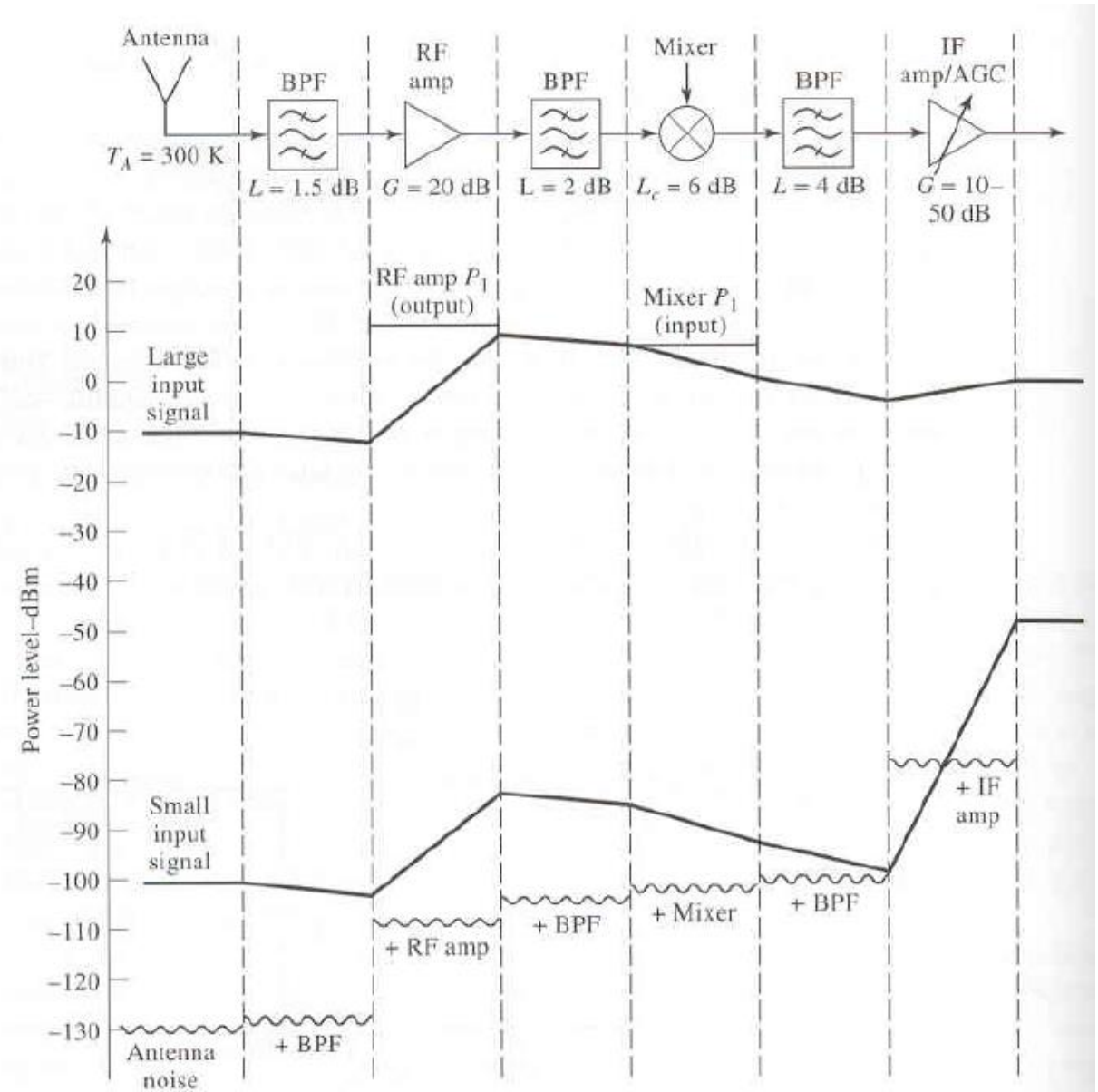


$$\frac{S_o}{N_o} = \frac{S_i}{kBT_{\text{SYS}}} = \frac{S_i}{kB[\eta_{\text{rad}}T_b + (1 - \eta_{\text{rad}})T_p + (L_T - 1)T_p + L_T T_{\text{REC}}]}$$

System	SNR (dB)
Analog voice	5–10
Analog telephone	25–30
Analog television	45–55
AMPS cellular	18
AM-PCM	30–40
QPSK ($P_e = 10^{-5}$)	10

Dynamic Range

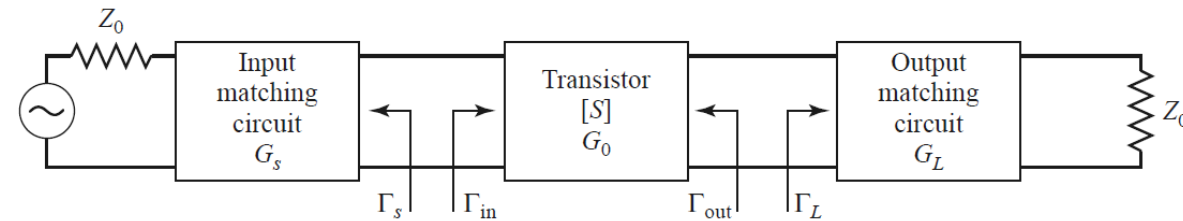
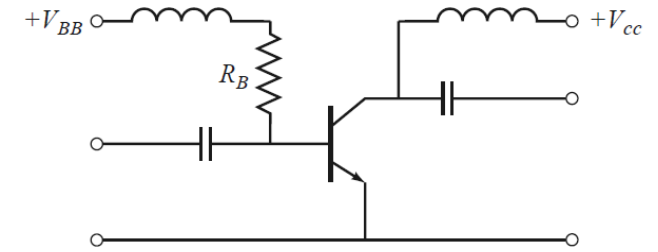
- “Ceiling” limited by compression
- “Floor” limited by noise



Important RF circuits

Low noise amplifiers

- Transistor, biasing, matching
- Match for
 - Gain
 - Complex conjugate power match
 - Noise
 - NF_{\min} , R_N , Γ_{opt} in datasheet
 - Stability
 - ... It's a trade-off.
- Usually multiple stages

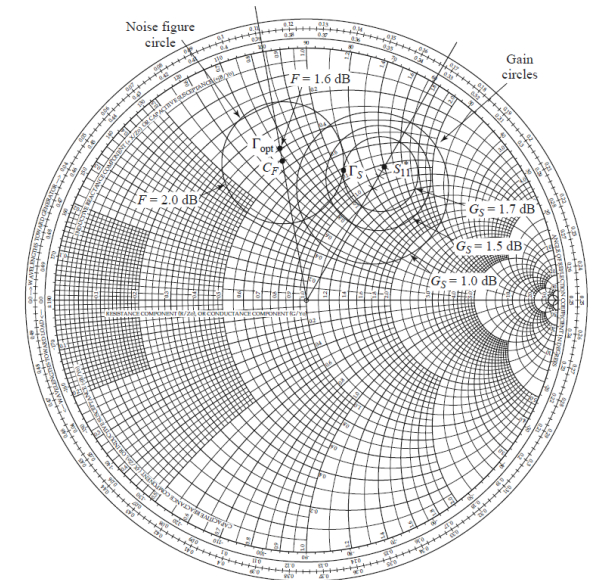


$$G_S = \frac{1 - |\Gamma_S|^2}{|1 - \Gamma_{in}\Gamma_S|^2},$$

$$G_0 = |S_{21}|^2,$$

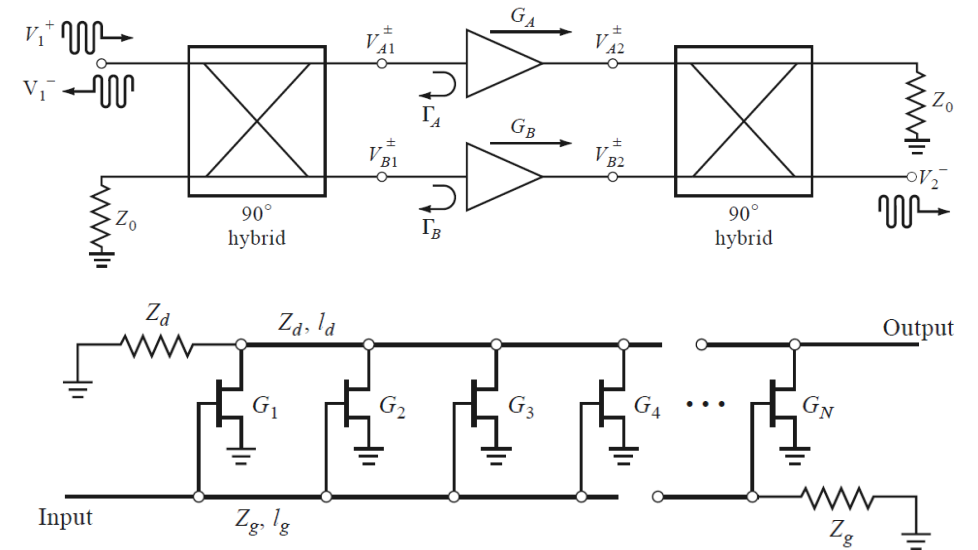
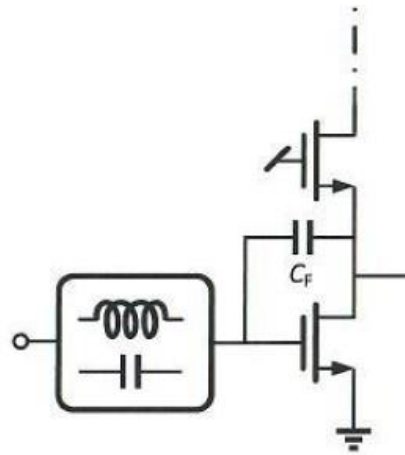
$$G_L = \frac{1 - |\Gamma_L|^2}{|1 - S_{22}\Gamma_L|^2}.$$

$$N = \frac{|\Gamma_S - \Gamma_{\text{opt}}|^2}{1 - |\Gamma_S|^2} = \frac{F - F_{\min}}{4R_N/Z_0} |1 + \Gamma_{\text{opt}}|^2$$



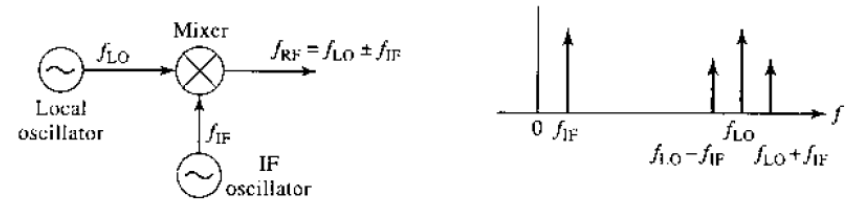
Broadband amplifiers

- Balanced amplifiers
- Distributed amplifiers
- Apply feedback
 - Stability!

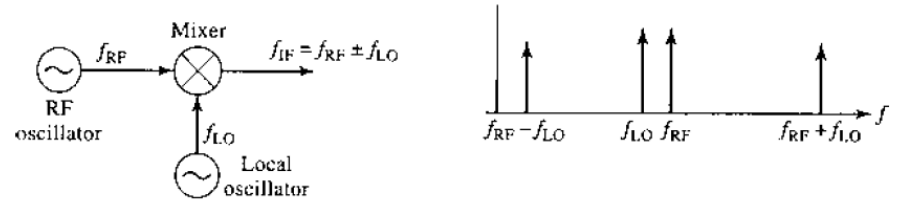


Mixers

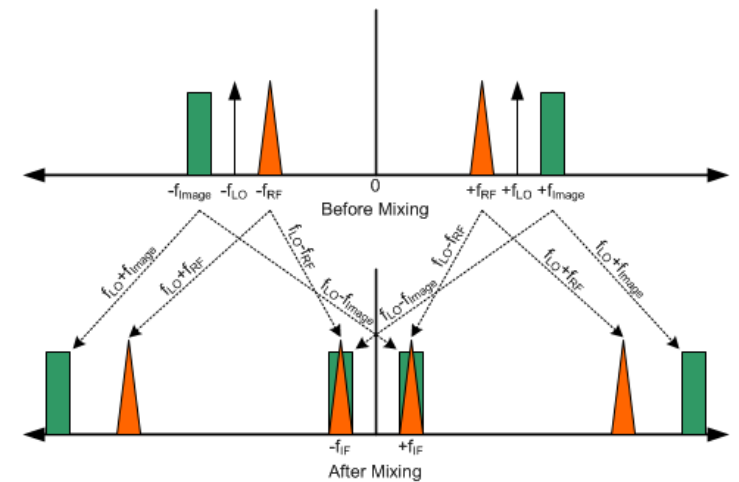
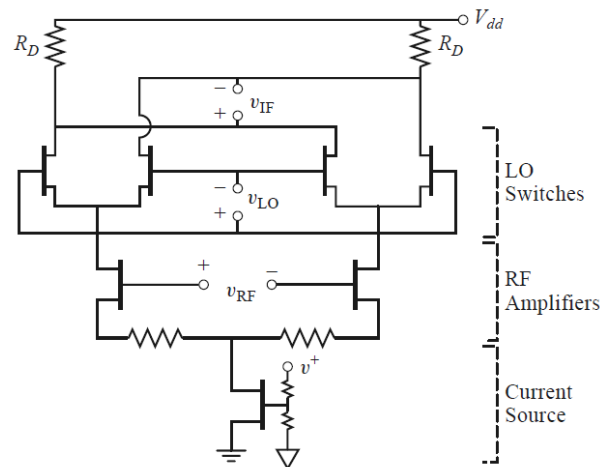
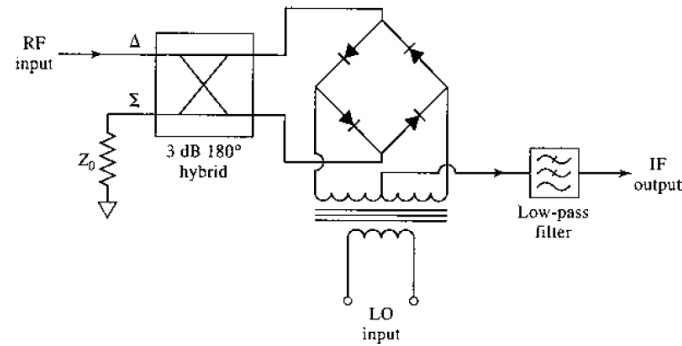
- 3-port device for frequency translation
- Image frequencies!
- Diode circuits
- Transistor circuits
 - Gilbert cell
- Harmonic versions



(a)

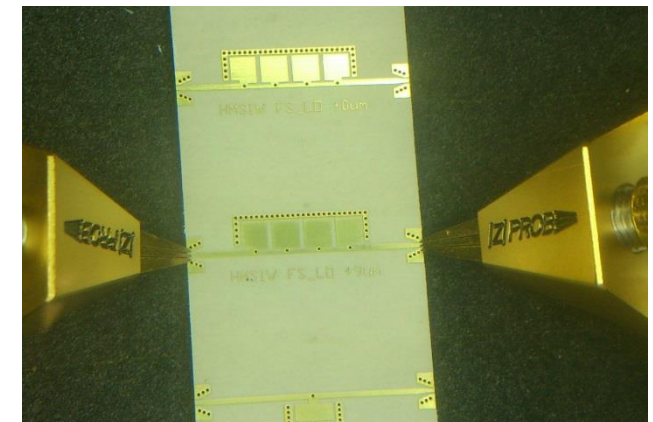
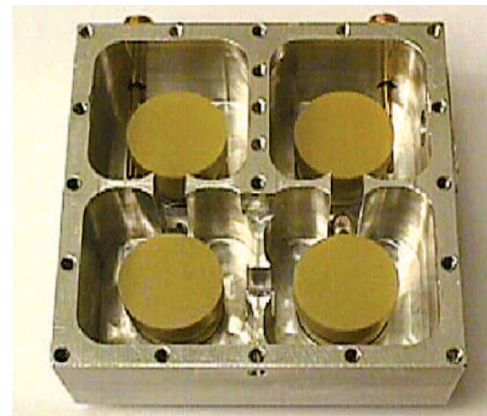
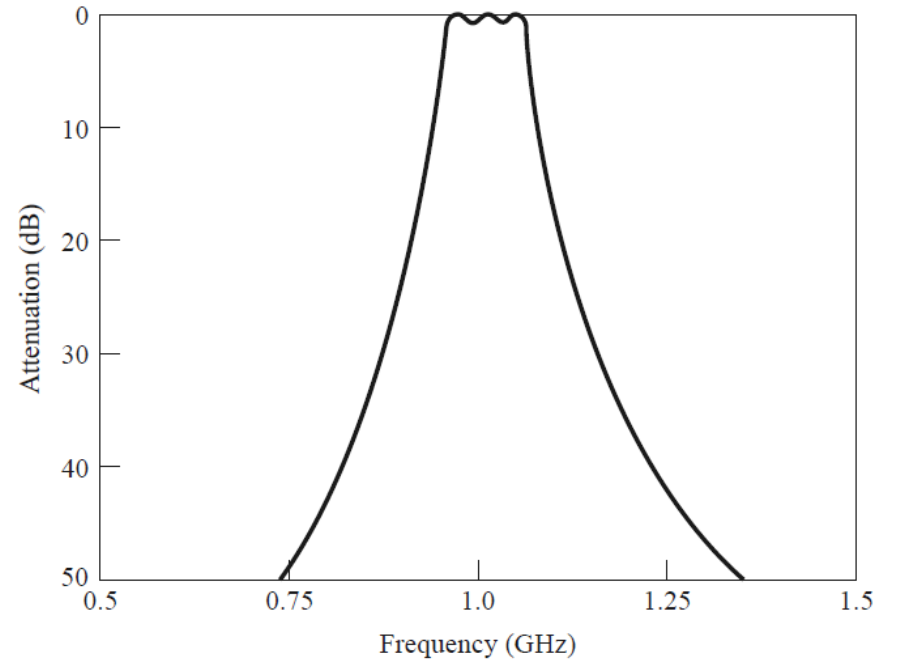


(b)



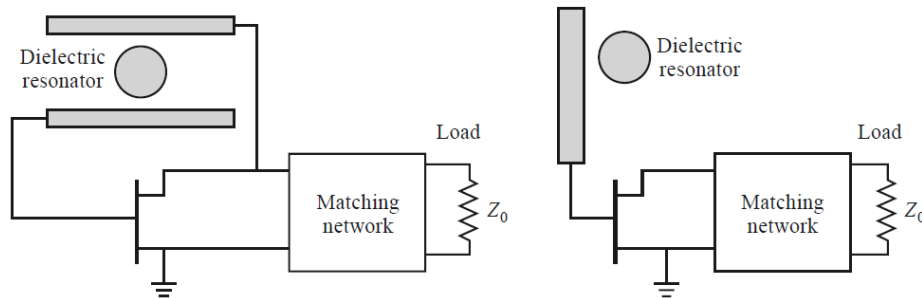
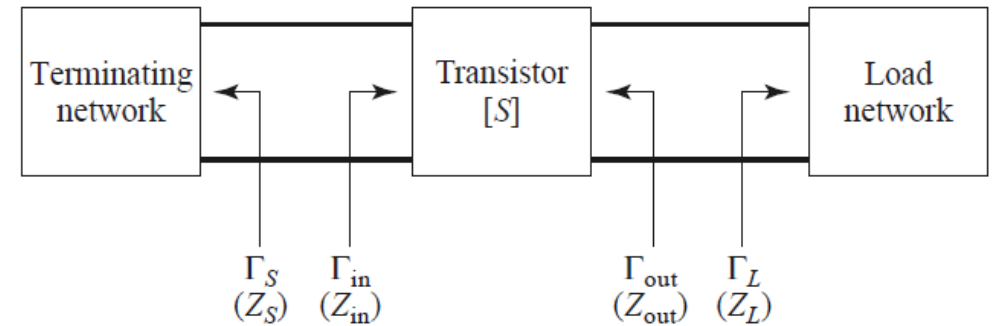
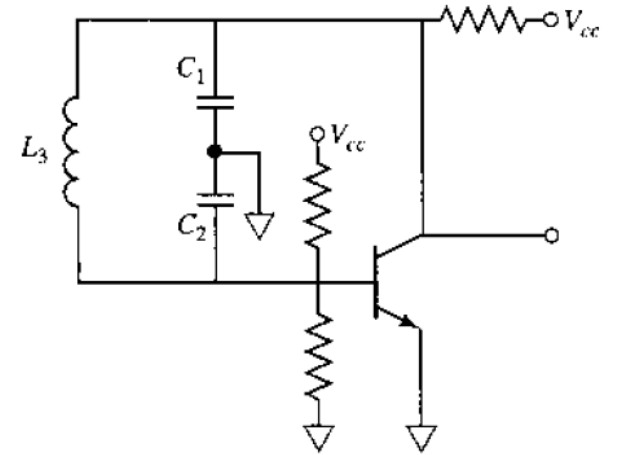
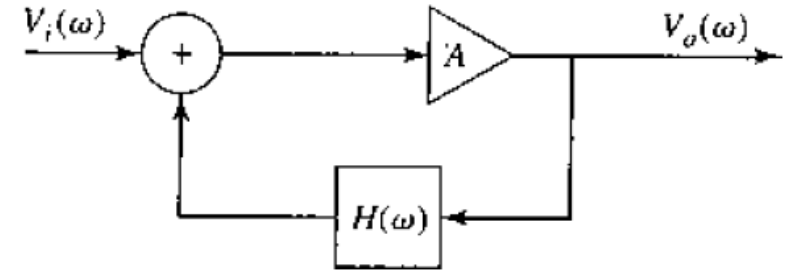
Filters

- Low-pass, high-pass, band-pass, band-stop
- Frequency selective transmission
- Limits received noise band
- Suppresses mixing products
- Reject interferers
- More elements:
 - More selective
 - More loss



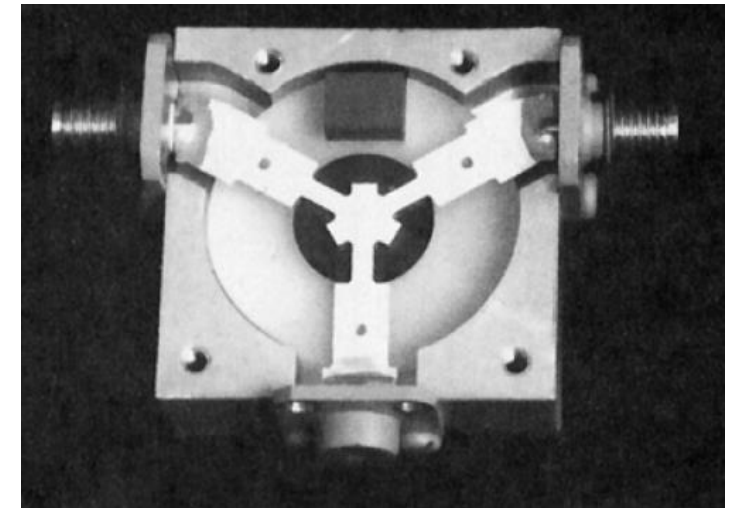
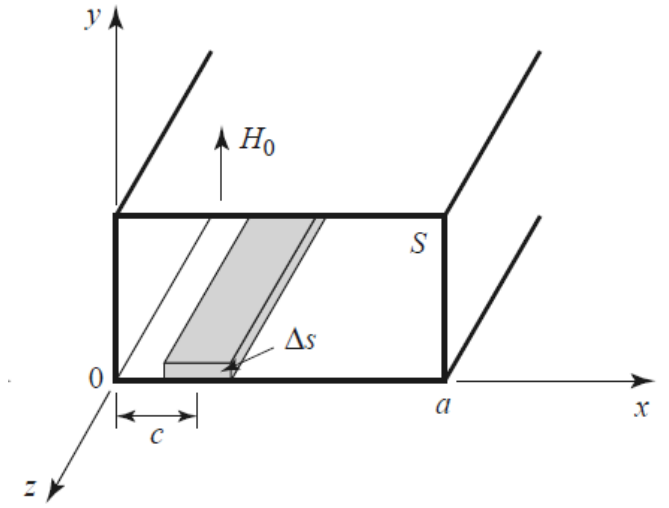
Oscillators

- Generate a steady sinusoid
- Characterized by
 - Power
 - Phase noise
 - Tunability
- Gain + a stable feedback
 - Can use a stable reflection as well



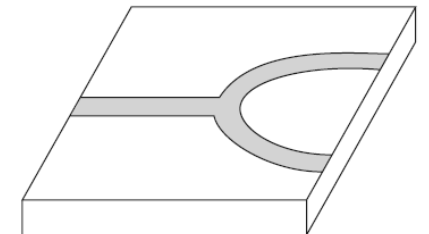
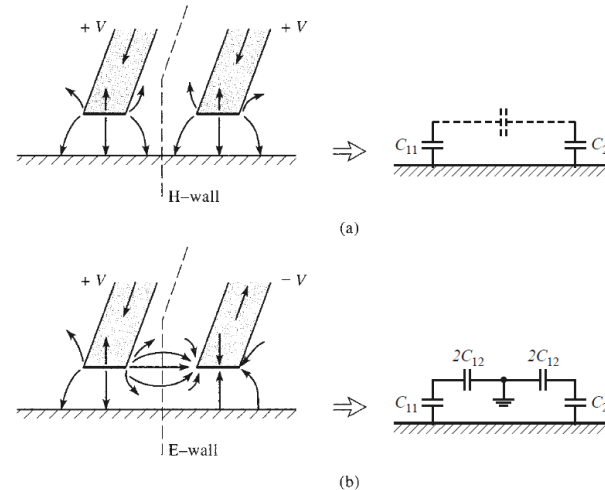
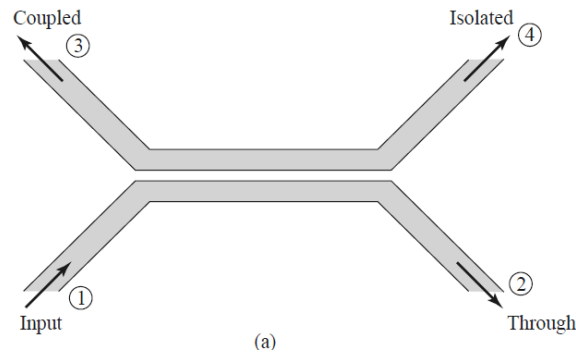
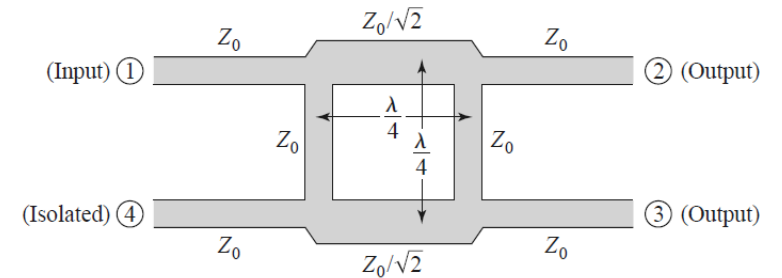
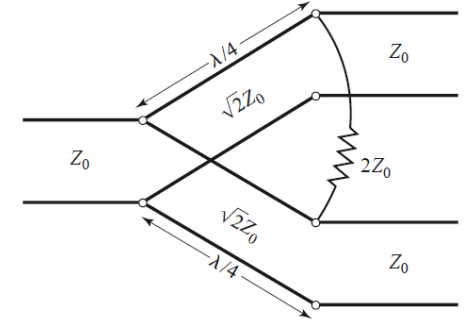
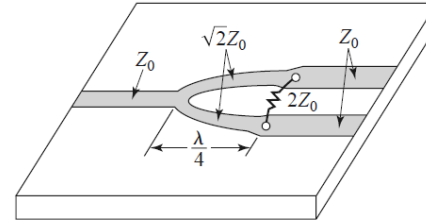
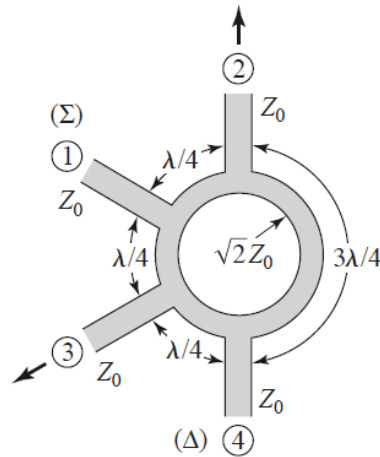
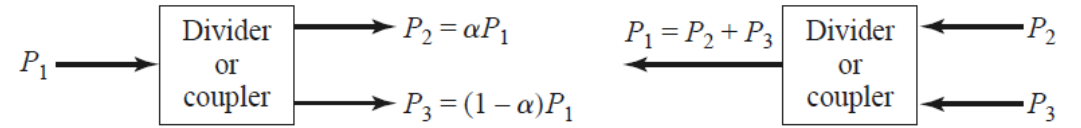
Isolators

- RF transmission in one direction, but not the other
 - $S_{21} \approx 0$ dB, $S_{12} < -40$ dB
 - Usually ferromagnetic
- Used to control noise and leakage propagation
 - Eg. LO reflection from antenna
- Three-port: Circulator
 - Signal Merry-go-round



Couplers

- Split energy from source to outputs
- T-junction
 - 3-port
 - Wilkinson
- Quadrature Hybrid
- Directional
 - 4-port
- Rat Race



RF measurement equipment

Vector Network Analyser (VNA)

- Two or more ports
- Single frequency tone in
 - Monitors outputs at all other ports
- Linear S-parameters
 - Complex values
 - Can do power sweep
- Calibrated every time before use!



Spectrum Analyser

- Single input port
- Provides a view of the RF spectrum
 - Multiple tones / harmonics
 - Only P over frequency



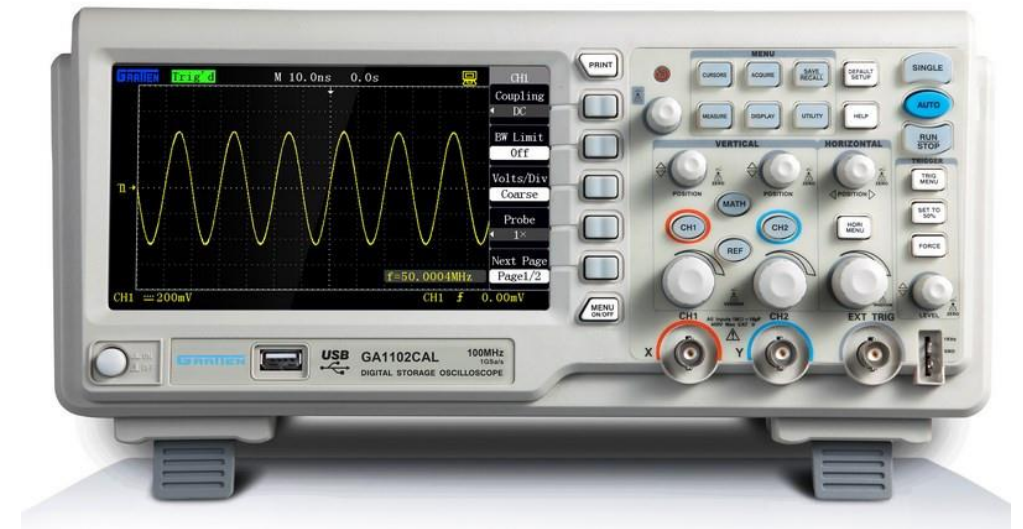
Signal generator

- Generates an output signal for testing
- Sinusoid of controlled
 - Frequency
 - Power
- Can produce modulated output
 - Digital modulation
 - Pulsed RF



Oscilloscope

- Voltage over time
- Modern versions go to RF frequencies
- Built-in processing available
- Need special probes



Power meter

- Total power over the sensitivity spectrum
- Usually thermal sensor
- Used to verify power levels



Torque wrench

- Used to connect RF connectors and cables
 - SMA, 3.5mm and up
 - Not for BNC
- Prohibits over-torque
- Always use this!
- NEVER USE AN ORDINARY WRENCH!



References

- D. M. Pozar, Microwave engineering, 4th ed. Hoboken, NJ: Wiley, 2012.
- D. M. Pozar, Microwave and RF Design of Wireless Systems. John Wiley & Sons, Inc., 2001.
- R. Ludwig and G. Bogdanov, RF Circuit Design. Pearson Education, 2009.
- I. J. Bahl, Lumped Elements for RF and Microwave Circuits. Artech House, 2013.